

Updated 14-August-
2019

Moving Coil Head-Amps

A collection of simulated circuits

www.hifisonix.com

July 2019

Version 1

Will remain a work in progress and updated from time to time.

Contents

- Introduction and Methodology
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- Moving Coil Head Amp Circuit Compendium
 - Simple single ended circuits
 - Simple balanced open loop designs
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- Miscellaneous Adenda
 - Power supply noise in simple balanced designs like the Hawking (aka 'Duraglit')
 - Arm/Cartridge Resonance Graph

Revision History

- 23-06-2019 – updated Richard Lee's Head Amps with notes provided by the designer; optimized noise performance on some of the single ended bipolar input designs
- 03-07-2019 – extensively updated and added newer designs
- 16-07-2019 – added Fermi and updated graphs
- 31-07-2019 - Updated Weinberg, Newton and added Archimedes; grouped the designs by type

Introduction – MC Head Amps

- In all the simulations, a stimulus of 500uV at 20 kHz is used
- Frequency response, distortion and power consumption were measured.
- The noise performance is quoted at 1 kHz. Where the circuit 1/f performance is markedly different from the others, this is noted – typically, the JFET designs show higher 1/f noise (~300Hz in the sims) than the bipolar input designs. On all the bipolar designs, the 1/f was ~10 Hz. Note also, the standard spice models used do not model the 1/f mechanism accurately.
- While the simulation figures should not be taken as absolutes, they do give some indication of the potential performance of the presented circuits.
- For the bipolar input device simulations, the Zetex ZTX851 and 951 are used as these are the lowest noise readily available transistors (2019).
- For the JFET input circuits, the BF862 model is used. Note that the BF862 is no longer available, but there are alternatives with similar noise performance.
- Attention: On some of the circuits, especially the bipolar input devices ones, further optimization of $r_{bb'}$ to match R_g through the adjustment of the device emitter current is possible – I leave this as an exercise for the reader (to borrow the words of Kendal Castor-Perry).
- I have avoided the temptation to simulate circuits with massive numbers of parallel input devices – this investigation is about practical audio circuits.

Device Models & Sim Methodology

Zetex Device Models

- [ZTX951 PNP Device](#)

```
.MODEL ZTX951 PNP IS=1.3766E-12 NF=1.013 BF=187 IKF=5.0 VAF=66.3  
+ISE=1.4E-13 NE=1.41 NR=1.0099 BR=56 IKR=0.9 VAR=33 ISC=1.7E-12  
+NC=1.4 RB=1.2 RE=0.020 RC=0.0255 CJC=287E-12 MJC=0.4522  
+VJC=0.4956 CJE=1.15E-9 TF=0.83E-9 TR=20E-9
```

- [ZTX851 PNP Device](#)

```
.MODEL ZTX851 NPN IS =1.0085E-12 NF =1.0001 BF =240 IKF=5.1 VAF=158  
+ ISE=2E-13 NE =1.38 NR =0.9988 BR =110 IKR=5.5 VAR=46  
+ ISC=4.6515E-13 NC =1.334 RB =1.5 RE =0.018 RC =0.015  
+ CJC=155E-12 MJC=0.4348 VJC=0.6477 CJE=1.05E-9  
+ TF =0.79E-9 TR =24E-9
```

- [BF862 JFET](#)

```
.MODEL BF862 NJF( VTO=-5.083E-1 BETA=3.394E-2 LAMBDA=2.426E-2 IS=1.19E-13  
N=1.255 + ISR=3P NR=2 RS=0.5 RD=0.5 BETATCE=-0.5 + VTOTC=-2E-3 ALPHA=1E-3  
VK=6.0E2 M=0.6 PB=0.5 + FC=0.5 CGS=9.5P CGD=7.5P KF=8.75E-17 AF=1 + MFG=NXF)
```

Attention: The RB specifications for the Zetex devices are not specified in the data sheet. These values were measured by a number of sources on the web and confirmed by various members of the DIY Audio community.

Simulations

- Rgen = 5 Ohms
- Rgen = 10 Ohms
- Measure supply current
- Check Frequency response – only report if anomalous – i.e. 20 Hz-20 kHz +0dB -0.d dB
- Measure distortion

Notes

- An ideal voltage source is used for the power supply since we are only interested in the native noise performance of the different circuits.

Noise Performance of the circuits in pico V/rt Hz

Sorted on Rg = 5 Ohms

Design	5 Ohms	10 Ohms
Weinberg	322	460
James Chadwick	327	462
Archimedes	339	468
Planck	340	466
Newton	353	472
Hawking	373	481
Sommerfeld	378	511
Maxwell	388	502
Heisenberg	408	504
Fermi	459	565
Born	460	560
DeBroglie	470	560
Pauli	470	563
JJ Thompson	480	570
Feynman	483	586
Kip Thorne	490	570
Schrodinger	490	590
Boltzmann	526	612
Julian Schwinger	572	670
Einstein	616	800
Gell-Mann	740	829
Rutherford	758	833
Gamow	804	866
Dirac	1100	1100
Bethe	1116	1240
Faraday	1300	1400
Galileo	1500	1600
Hugens	2900	3100

These figures include
the generator
resistance noise – 5
Ohms and 10 Ohms

Updated 31-Jul-2019

Sorted on Rg = 10 Ohms

Design	5 Ohms	10 Ohms
Weinberg	322	460
James Chadwick	327	462
Planck	340	466
Archimedes	339	468
Newton	353	472
Hawking	373	481
Maxwell	388	502
Heisenberg	408	504
Sommerfeld	378	511
Born	460	560
DeBroglie	470	560
Pauli	470	563
Fermi	459	565
JJ Thompson	480	570
Kip Thorne	490	570
Feynman	483	586
Schrodinger	490	590
Boltzmann	526	612
Julian Schwinger	572	670
Einstein	616	800
Gell-Mann	740	829
Rutherford	758	833
Gamow	804	866
Dirac	1100	1100
Bethe	1116	1240
Faraday	1300	1400
Galileo	1500	1600
Hugens	2900	3100

Noise Performance

- The difference between the best and the worst in the amplifier only noise (ignoring generator resistance noise) is ~15 dB
- However, when the generator source resistance noise is factored in, the noise differences are less stark and for a 10 Ohm generator resistance, the difference is 10.4 dB.
- As the generator resistance increases, the differences in decrease as the amplifier input referred noise is swamped by the generator resistance noise.
- The next two graphs show the amplifier performance best to worst for both amplifier noise only and the 'real world' noise including the generator resistance.

Updated 31-Jul-2019

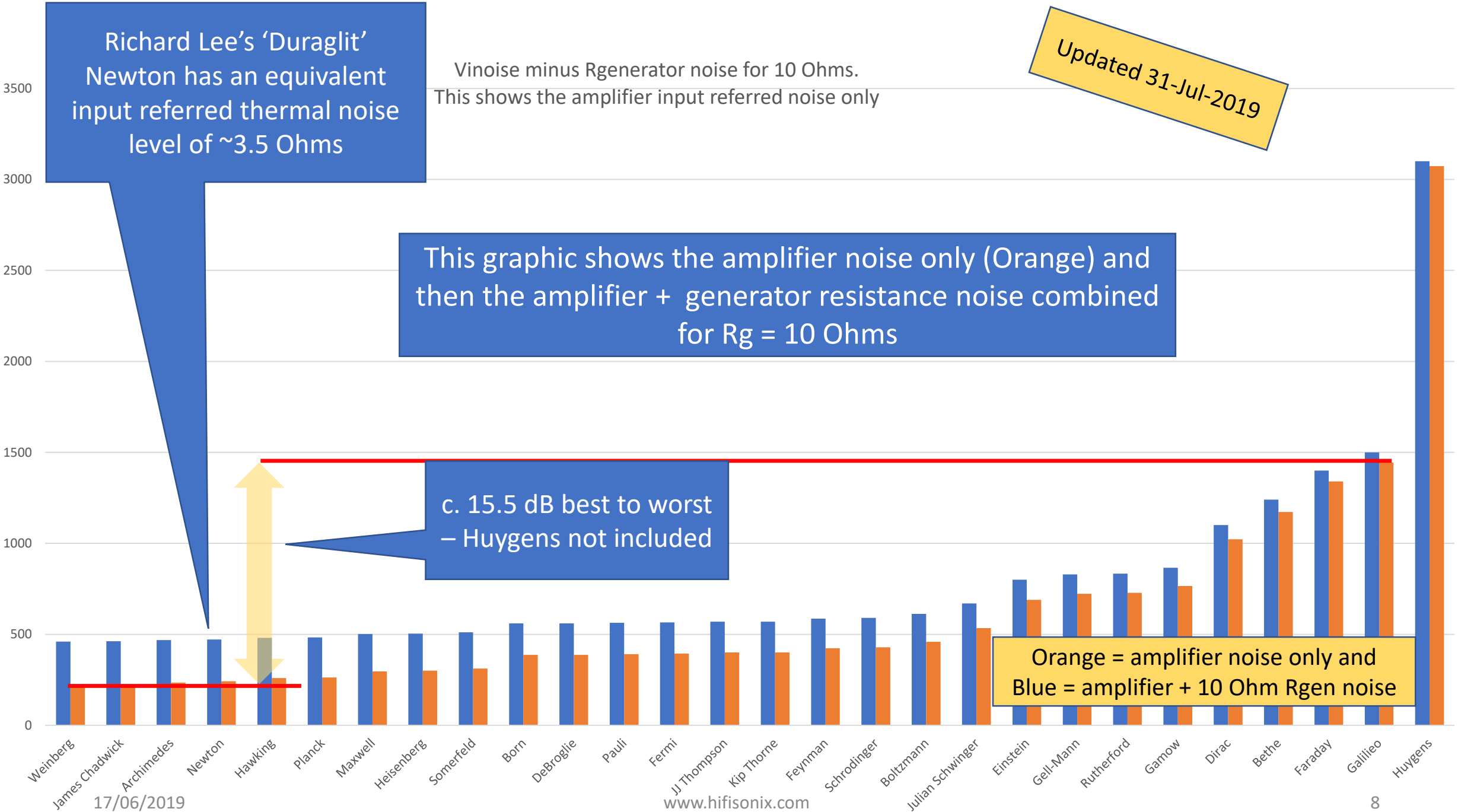
Richard Lee's 'Duraglit'
Newton has an equivalent
input referred thermal noise
level of ~3.5 Ohms

Vinoise minus Rgenerator noise for 10 Ohms.
This shows the amplifier input referred noise only

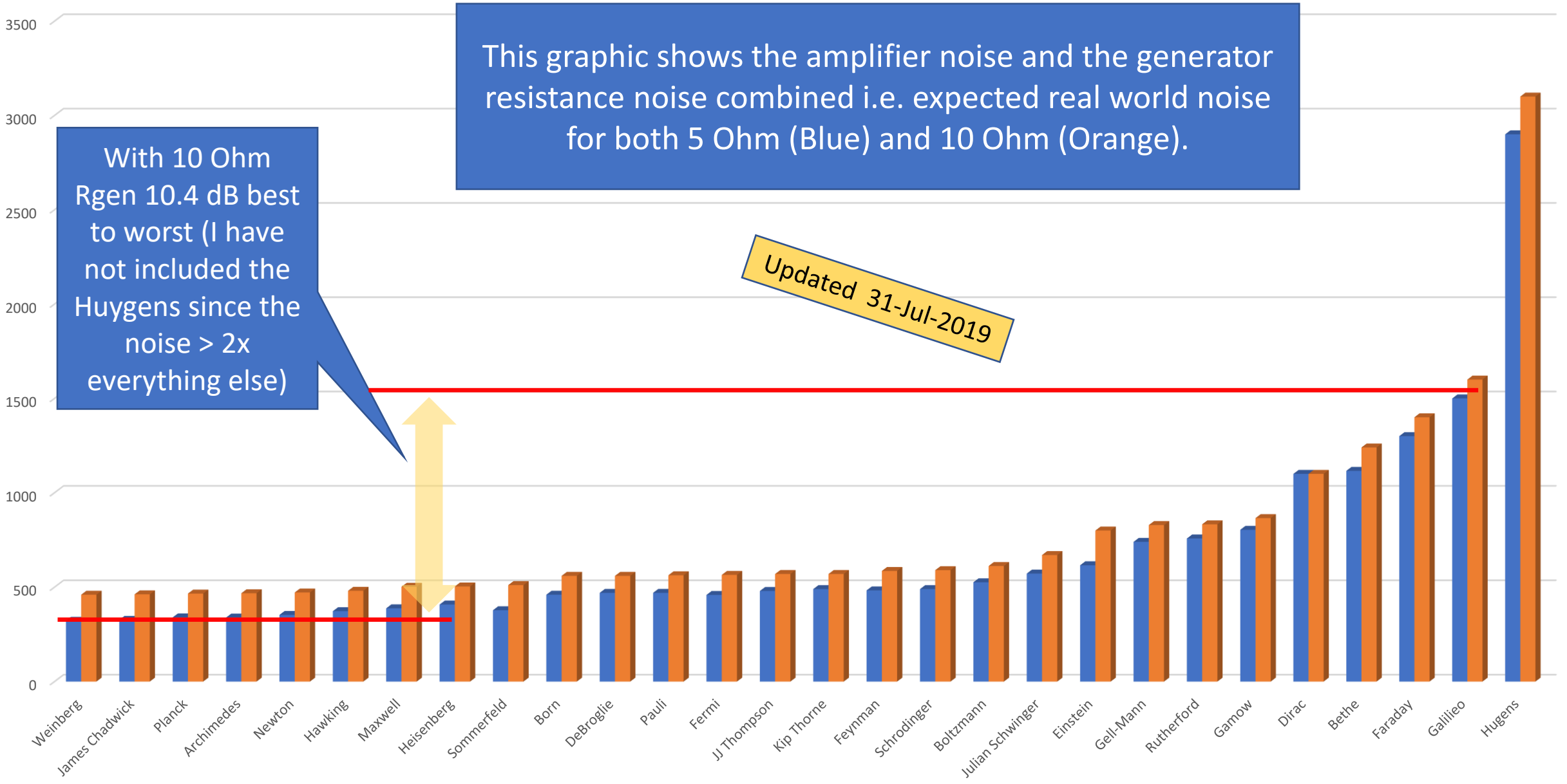
This graphic shows the amplifier noise only (Orange)
and then the amplifier + generator resistance noise combined
for $R_g = 10\text{ Ohms}$

c. 15.5 dB best to worst
– Huygens not included

Orange = amplifier noise only and
Blue = amplifier + 10 Ohm Rgen noise



Noise performance of MC HHead Amp designs. These figures include the generator resistance



Noise – how source and amplifier noise add (1)

1. On the next slide is a table that shows how the amplifier noise and the source resistance noise add.
2. Select your total amplifier equivalent noise resistance on the y axis, your source resistance on the x axis and the intersection is the total equivalent input noise. Note: you must manually compute any noise current terms and add them to the voltage noise in RMS fashion – but note that for the simple circuits shown here, you can for the most part ignore current input noise.
3. What is immediately apparent from this is that having an amplifier that is much quieter than the source resistance gives little benefit.
 - For example, if the source resistance is 40 Ohms, a very quiet amplifier with an equivalent input noise voltage of 3.5 Ohms (something like the Hawking designed by Richard Lee in the presentation above) offers only about 1/3rd lower total system noise (0.83nV/rt Hz) noise than an amplifier with an equivalent input noise of 40 Ohms i.e. 1.15 nV/rt Hz.
 - On the other hand, if the source resistance is just 2 Ohms, but the amplifier equivalent noise resistance is 40 Ohms (akin to a JFET input stage), the difference is far more marked and the total system noise will be about 3.2x worse than the source resistance noise - .256 nV/rt Hz versus 0.83 nV/rt Hz.
4. So, as a general rule we can say:- If the amplifier equivalent noise resistance is not more than $\sim\sqrt{2}$ the source resistance noise, it will be just audible since the human ear cannot discern changes of <1.5dB in power level.

Noise – how source and amplifier noise add 2

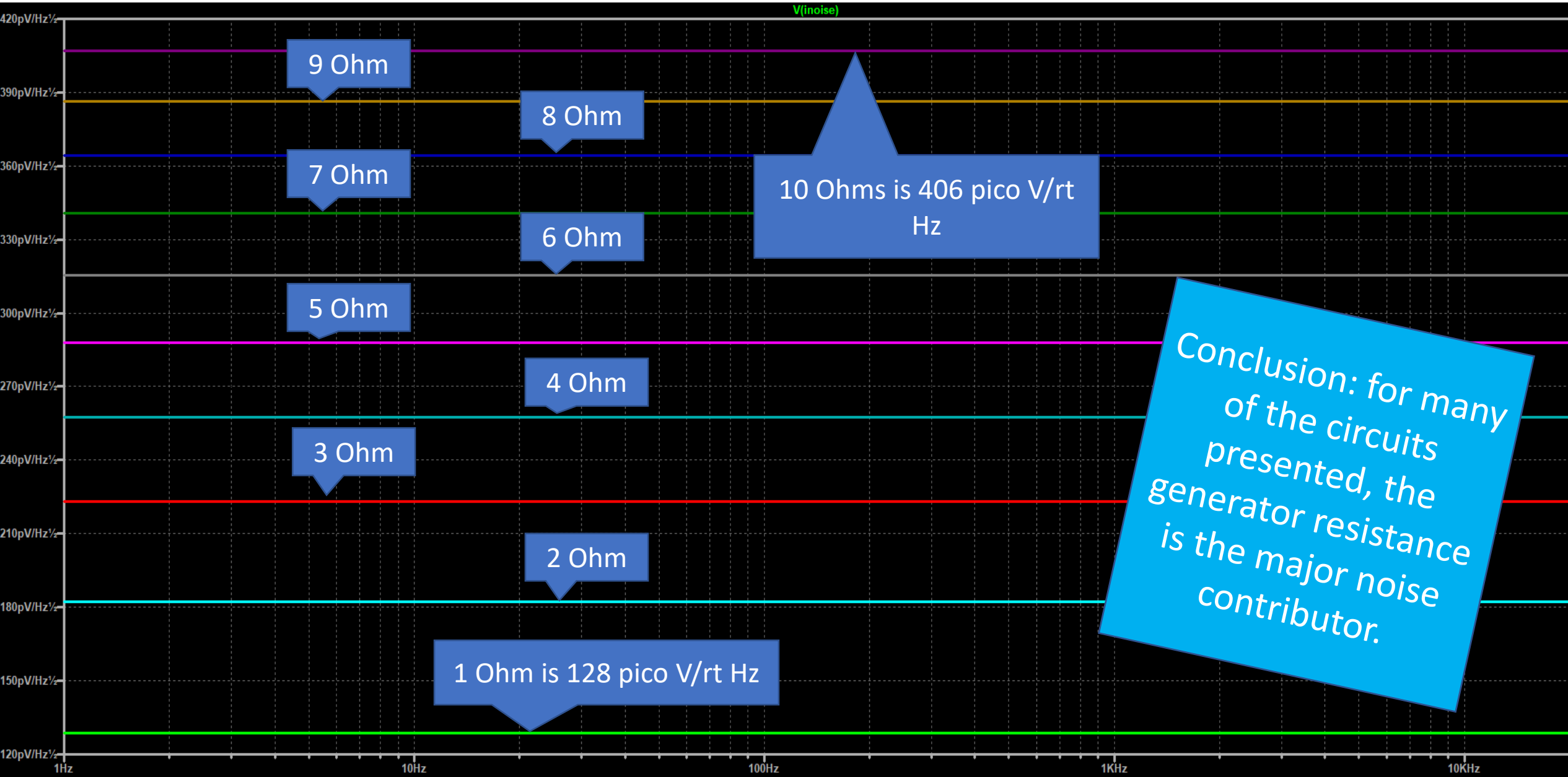
Generator Source Resistance

	2	4	6	10	20	40
2	2.56E-10	3.14E-10	3.62E-10	4.44E-10	6.01E-10	8.30E-10
4	3.14E-10	3.62E-10	4.05E-10	4.79E-10	6.27E-10	8.49E-10
6	3.62E-10	4.05E-10	4.44E-10	5.12E-10	6.53E-10	8.68E-10
10	4.44E-10	4.79E-10	5.12E-10	5.73E-10	7.01E-10	9.05E-10
20	6.01E-10	6.27E-10	6.53E-10	7.01E-10	8.10E-10	9.92E-10
40	8.30E-10	8.49E-10	8.68E-10	9.05E-10	9.92E-10	1.15E-09
60	1.01E-09	1.02E-09	1.04E-09	1.07E-09	1.15E-09	1.28E-09

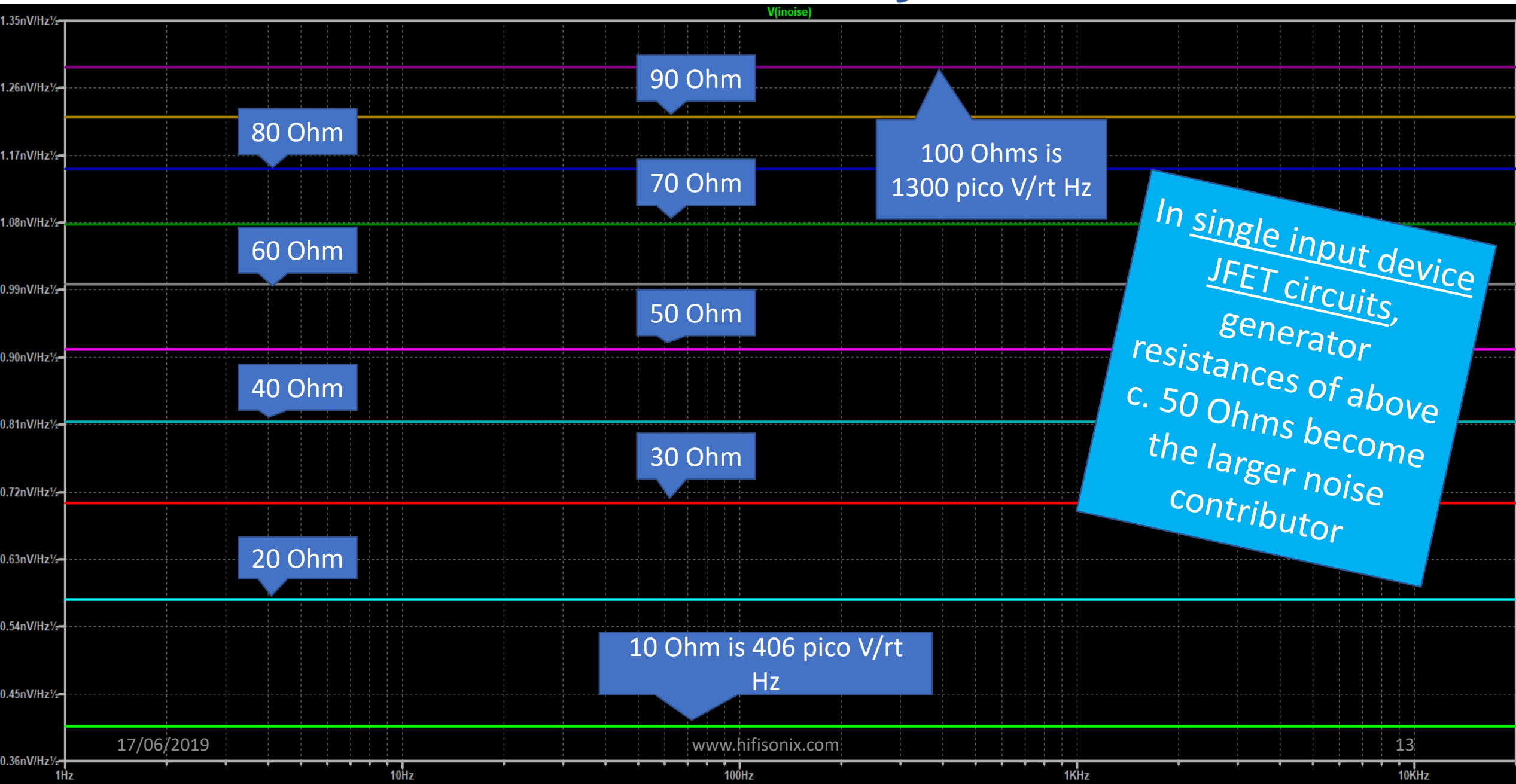
All figures are
Volts/rt Hz

$$*Total\ equivalent\ noise = \sqrt{(Inoise * Rs)^2 + Vnoise^2}$$

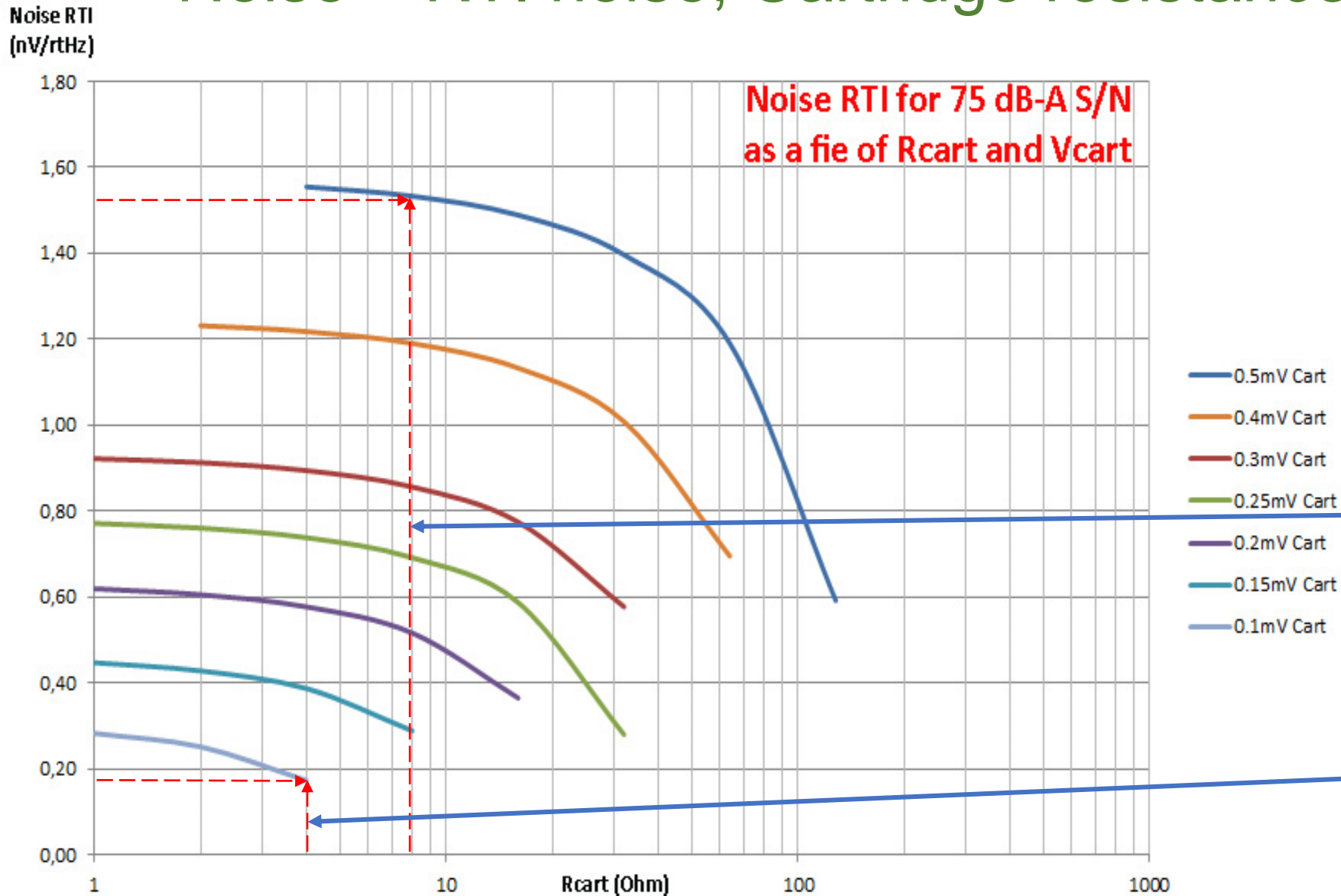
Reference: Resistor Noise Only – 1 to 10 Ohms



Reference: Resistor Noise Only – 10 to 100 Ohms



Noise – RTI noise, Cartridge resistance and Output



This graph by DIY Audio Member *Hans Polak* shows what the Referred To Input (RTI) total noise has to be equal to or lower to achieve a S/N ratio of 75 dB for a range of cartridge outputs and their associated generator resistances.

For example, with a cartridge resistance of **8 ohms**, as long as the total RTI input is less than $\sim 1.5 \text{ nV/rt Hz}$ and the cartridge output is 0.5mV or more, you are good to go. If your cartridge is only 0.1mV output, the cartridge resistance cannot be higher than **3 Ohms** and the total RTI noise no higher than $\sim 180 \text{ pico V/rt Hz}$

The following section presents sim results of a range of MC Head Amplifier circuits

All the designs are named after famous physicists so if you want to discuss a circuit, just refer to its 'physicist' name*.

No attempt has been made to provide loop compensation in the designs where feedback is employed (other than the Galileo which has been built and tested) – this is left up to the reader to investigate (the LTspice XII files are available on the hifisonix.com website on the same page this file is located at). The primary focus of this investigation is to look at noise, current consumption and distortion.

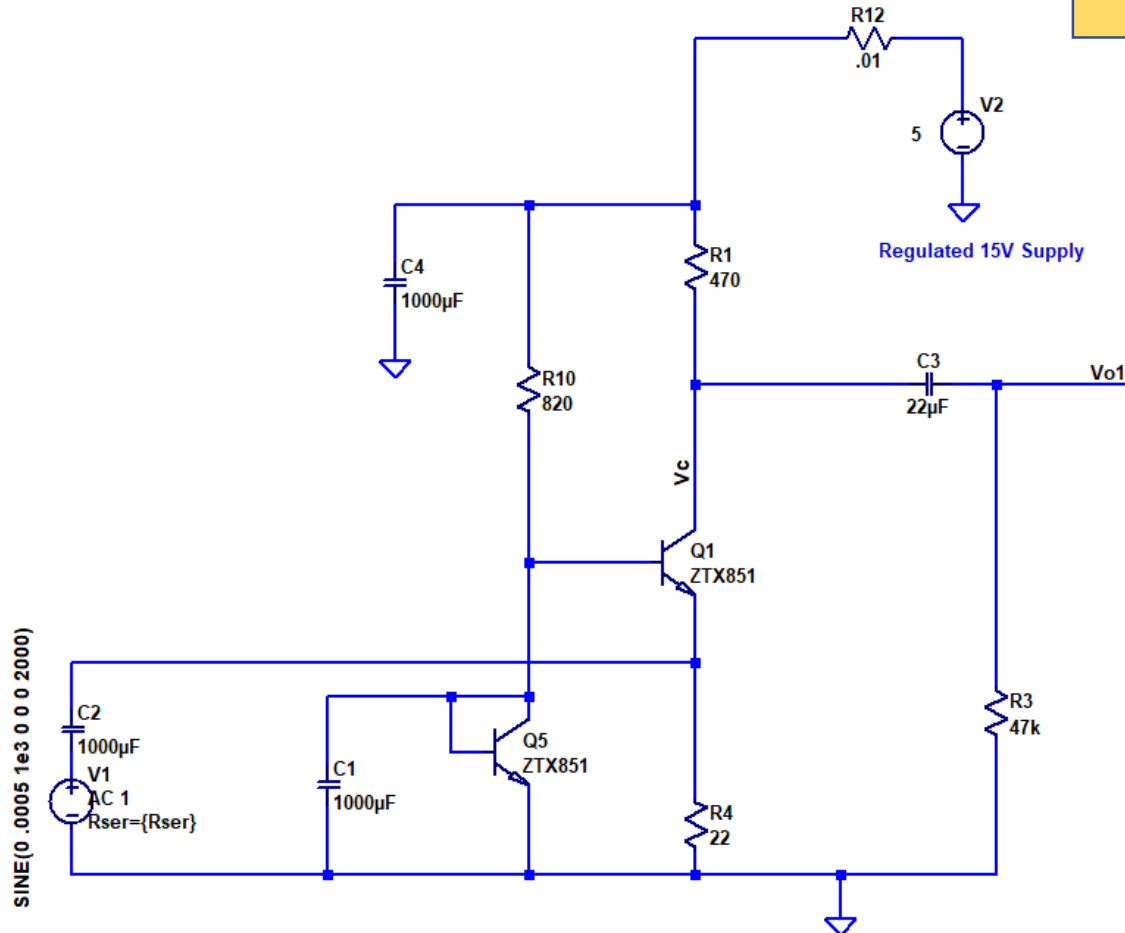
*You can read about these scientists by clicking on the link on the bottom RHS corner

Simple Single Ended Open Loop Designs

Einstein MC Pre - 616/800 pico V/rt Hz

1/f corner < 10 Hz; current draw c. ~8.5 mA per channel; distortion c. 0.25% @ 20kHz;
4Hz to 2MHz +0dB -3 dB; -1.5 dB at 20 Hz Gain Varies with Generator coil resistance

In all the simulations that follow, the quoted noise INCLUDES the generator resistance noise i.e. it is the real world noise for the circuit with a 5 Ohm and then a 10 Ohm generator resistance



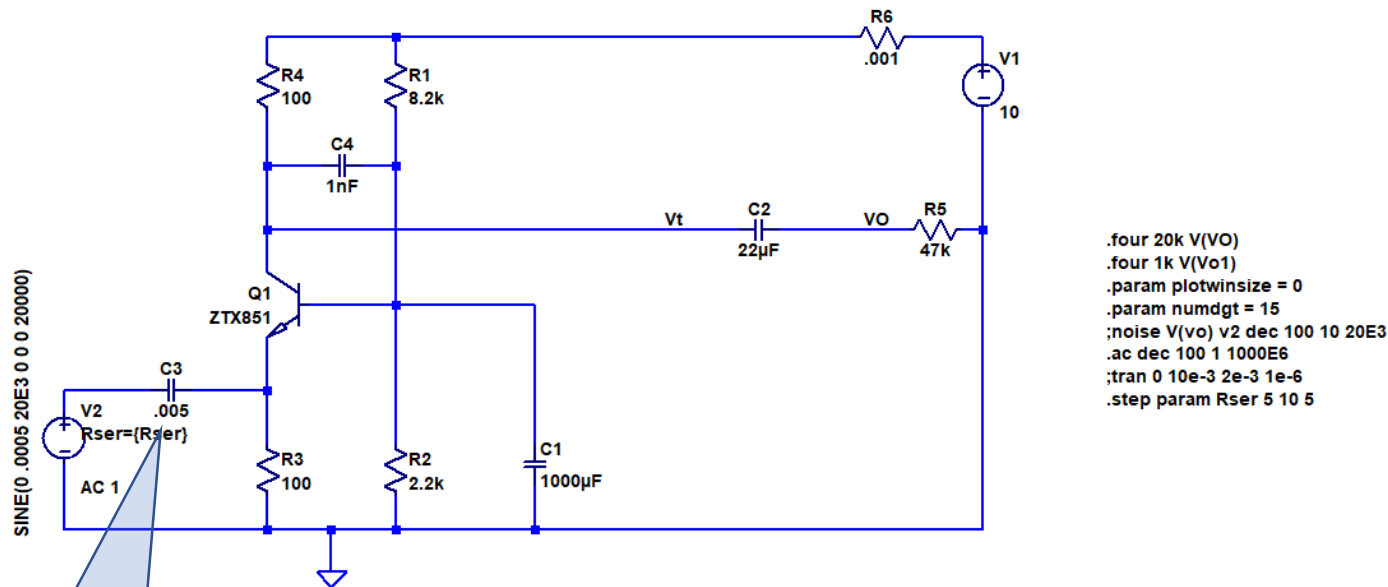
```
.four 1k V(Vo1)
.param plotwinsize = 0
.param numdgt = 15
.noise V(vo1) v1 dec 100 10 20E3
;ac dec 100 1 1000E6
;tran 0 10e-3 2e-3 1e-6
.step param Rser 5 10 5
```

A very simple circuit with good noise performance. Adjust the value of R10 for 3~4mA through R1

**'Maxwell' ultra simple MC Preamp; Distortion 0.033%; Noise 370/509 pico V/rt Hz
Isupply = 15mA; -0.5 dB at 20 Hz - requires LARGE C3; Zin is LOW**

Gain varies with generator resistance

$$AV = \sim 14x$$

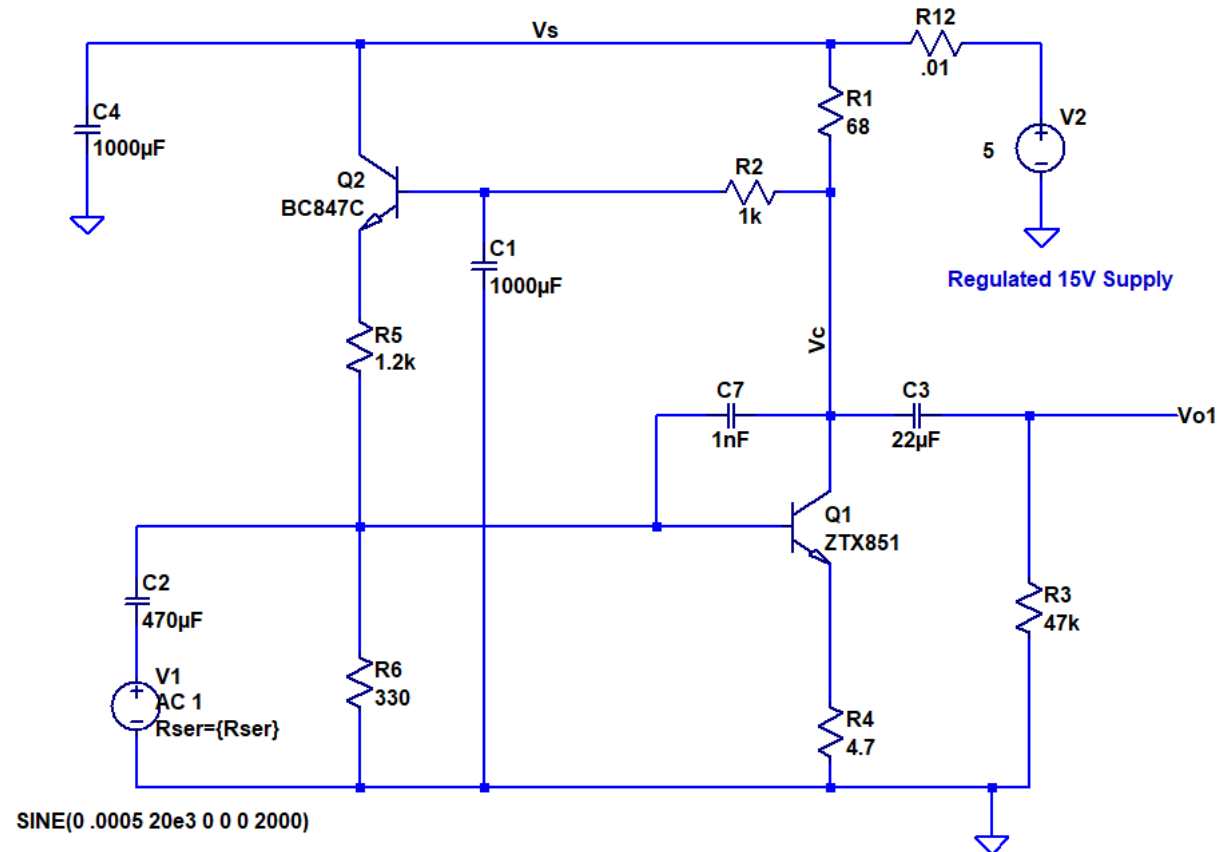


Large electrolytic

Very simple
circuit with
good noise
and distortion
performance.
Use a 4700uF
10V capacitor
for C3

Pauli low noise MC preamplifier 470/563 pV/rt Hz @ 1kHz

1/f corner < 10 Hz; current draw c. 18mA per channel; distortion c. 0.03% @ 20kHz;
2Hz to 2MHz +0dB -3 dB; based on a mic pre from AoE - Horowitz and Hill page 506 3rd Ed



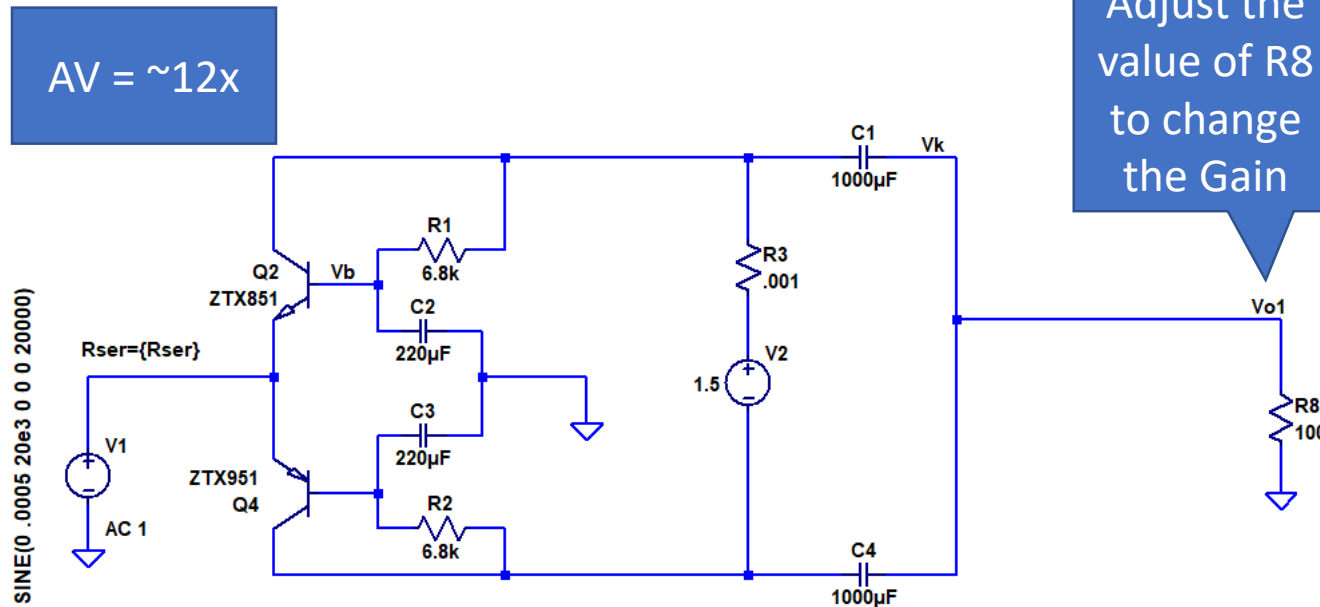
Simple, low
noise
amplifier with
very good
performance

```
.four 20k V(V2)  
.param plotwinsize = 0  
.param numdgt = 15  
.noise V(vo1) v1 dec 100 1 20E3  
;ac dec 100 1 100E6  
.step param Rser 5 10 5  
  
;tran 0 10e-3 2e-3 1e-7
```

Simple Balanced Open Loop Designs

'Hawking' 373/481 pico Volts/rt Hz ; Current supply ~5mA; Gain varies with generator source resistance; distortion 0.0068%

```
.four 20k V(Vo1)
.param plotwinsize = 0
.param numdgt = 15
;noise V(vo1) v1 dec 100 1 20E3
;ac dec 100 1 1000E6
.step param Rser 5 10 5
.tran 0 1e-3 0 1e-8
```



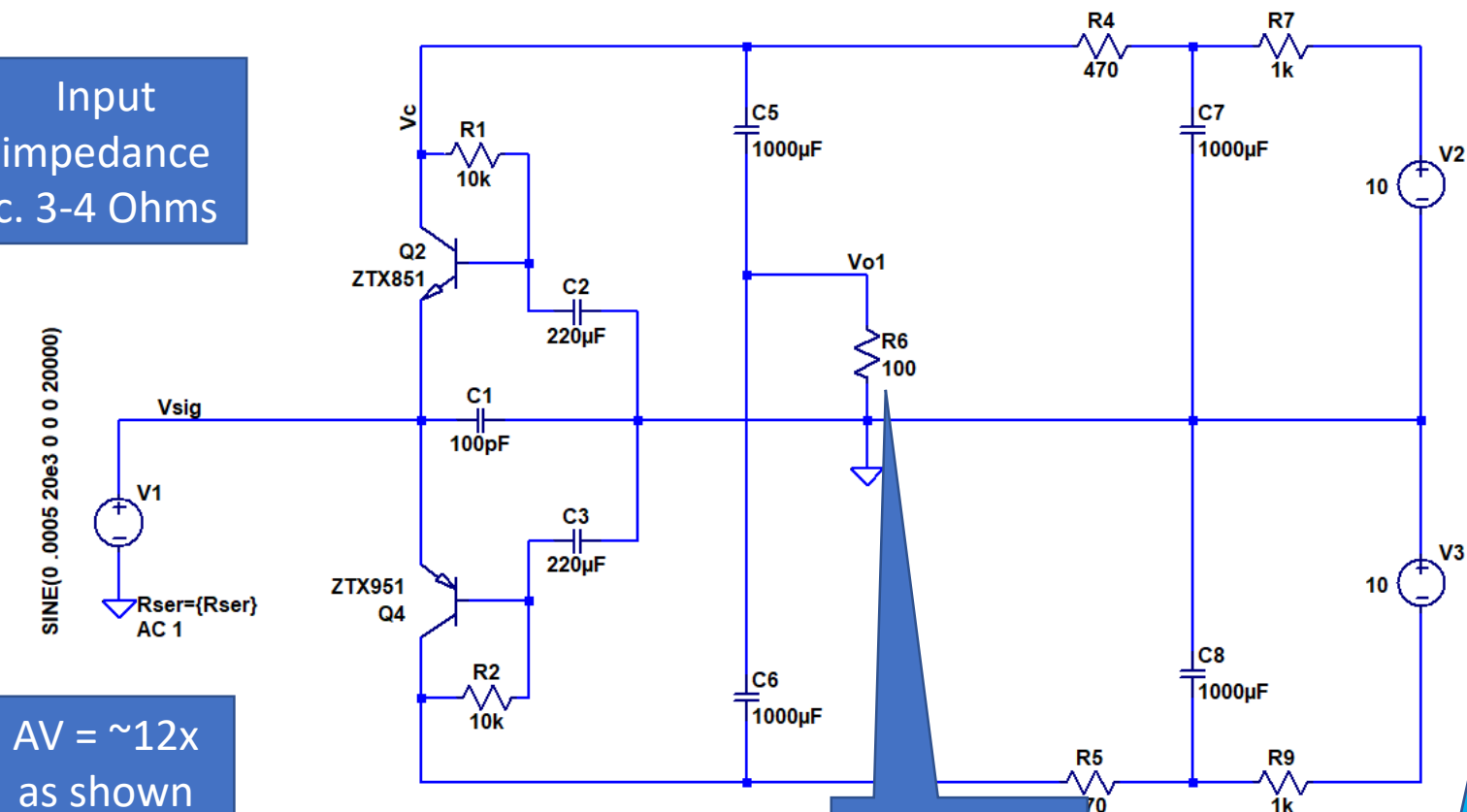
Richard Lee's
'Duraglit Special'
design from circa
1980; Note this is
battery powered;
suits low output,
low cartridge coil
resistance

C1 and C4 are set at 1000uF to ensure that the total load (C1, C4 and R8) remains flat down to very low frequencies to avoid LF gain peaking (in this case the -3dB frequency is 1.5 Hz). This applies to all the 'Duraglit' derivatives that follow

Newton after Richard Lee's Complementary MC Phono Pre - 353/472 pico V/rt Hz

Isupply c. 6.5mA per rail; distortion c. 0.015% @ 20kHz; 0.5~ 2MHz +0dB -3 dB; Gain Varies with Generator coil resistance. The ZTX951/851 devices shown offer the best rbb' currently (2019) available and will yield lowest noise voltages (notes provided by designer R. Lee - updated 23-06-2019).

Input impedance c. 3-4 Ohms



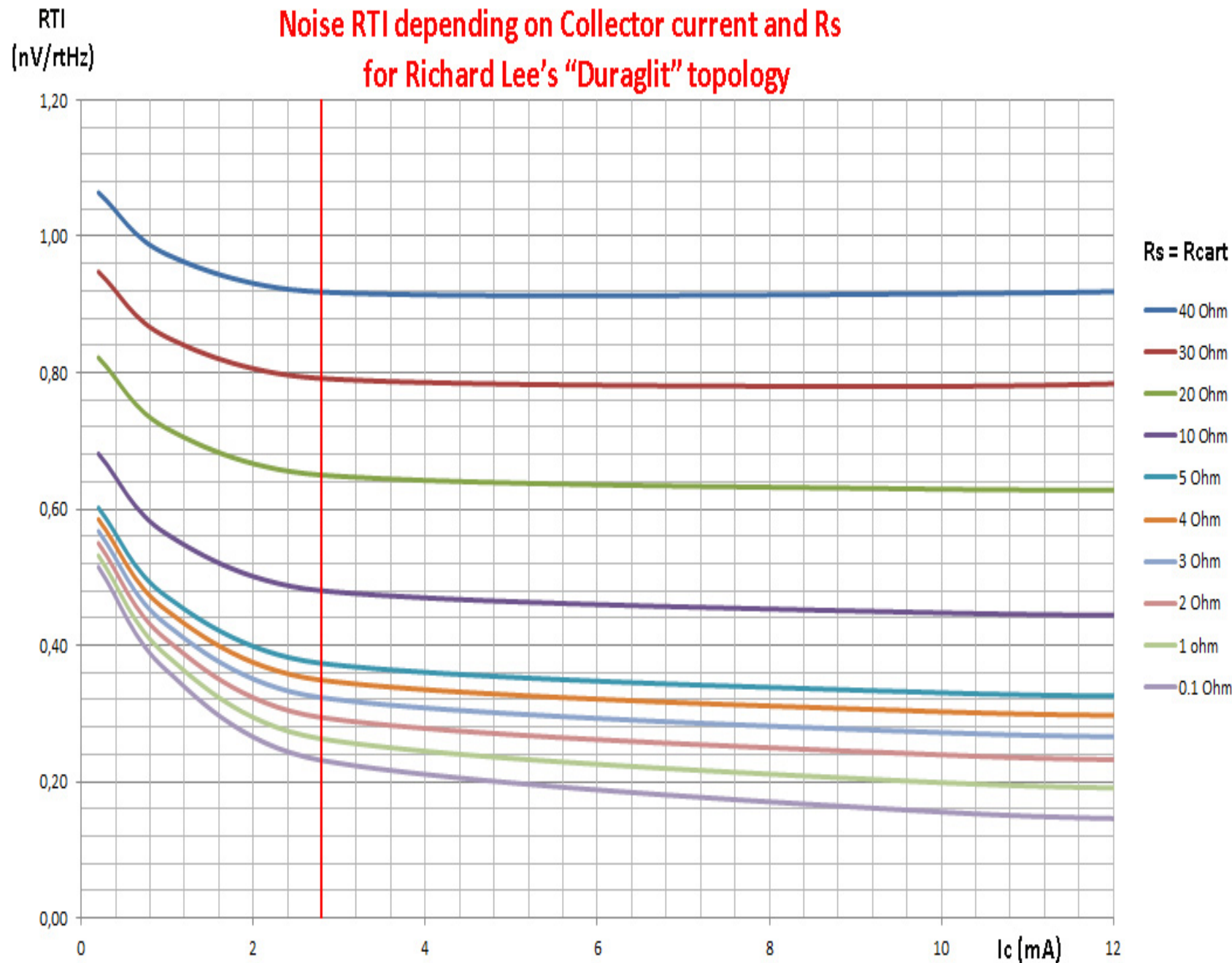
AV = ~12x as shown

Circuit value re-optimized for lowest noise 23 Jul 2019

17/06/2019

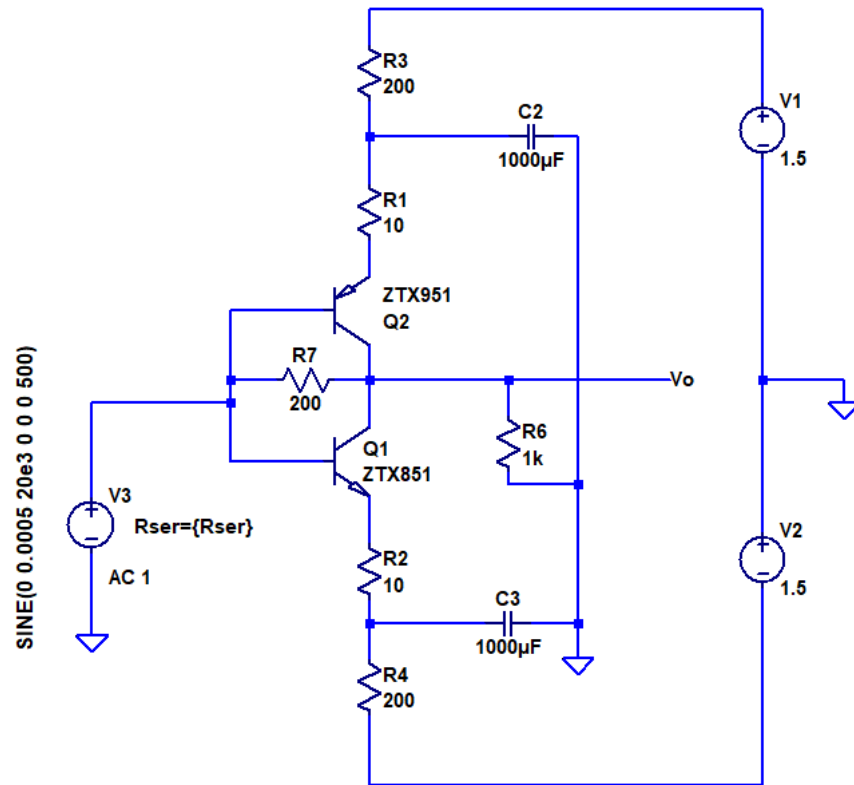
Ultra simple very high performance MC amp – best 'bang for buck' design of the lot; powered off +/-10 V rails; optimized for 3~4 Ohm cart resistances. Amplifier only noise is c. 242 pV/rt Hz. With Rgenerator = 3 Ohms. **total** noise is 292 pV/rt Hz

https://en.wikipedia.org/wiki/Isaac_Newton



DIY Audio member *Hans Polak*'s graphic showing how noise performance of the two previous Richard Lee designs varies with collector current and cartridge generator coil resistance. For all of the cartridge coil resistances, best performance starts with I_c at c. 2.5-3mA with little to be gained in real terms beyond that in higher generator resistance cartridges. For very low generator resistance cartridges (say <5 Ohms), increasing I_c by 3x to 4x will bring some added noise performance improvement

The Schrodinger MC Head Amp (after John Curl); noise 490/590 pico Volt/rt Hz; distortion 12ppm/15ppm; Isupply ~4mA per rail

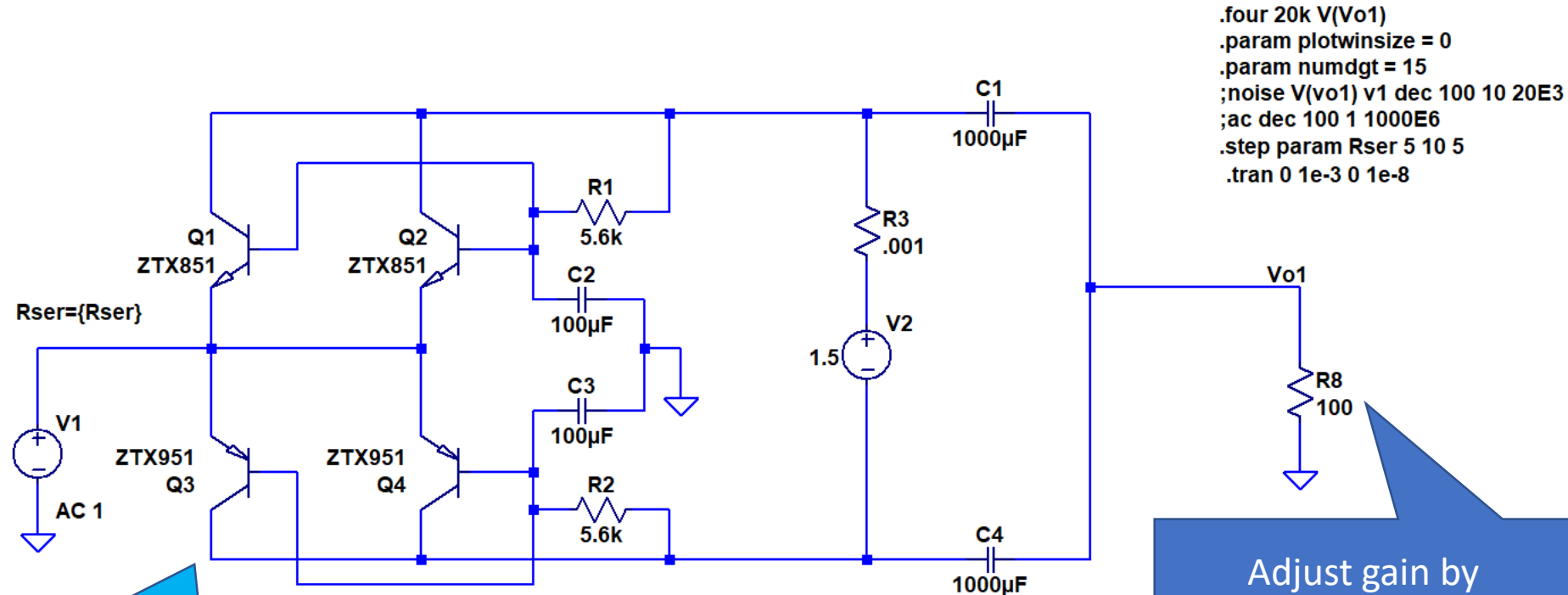


AV = ~12x. Adjust R6
to change gain

```
.four 20k V(VO)
.four 1k V(Vo1)
.param plotwinsize = 0
.param numdgt = 15
.noise V(vo) v3 dec 100 10 20E3
;ac dec 100 1 1000E6
;tran 0 10e-3 2e-3 1e-6
.step param Rser 5 10 5
```

Simple, low power
'current input'
virtual earth circuit
with good noise
performance

Planck Battery Powered MC Phono Pre; distortion 0.007% noise 340/466 pico V/rt Hz; Current supply ~6.5mA; Gain varies with generator source resistance.



Match all 4 transistor
Vbe's to better than
1mV

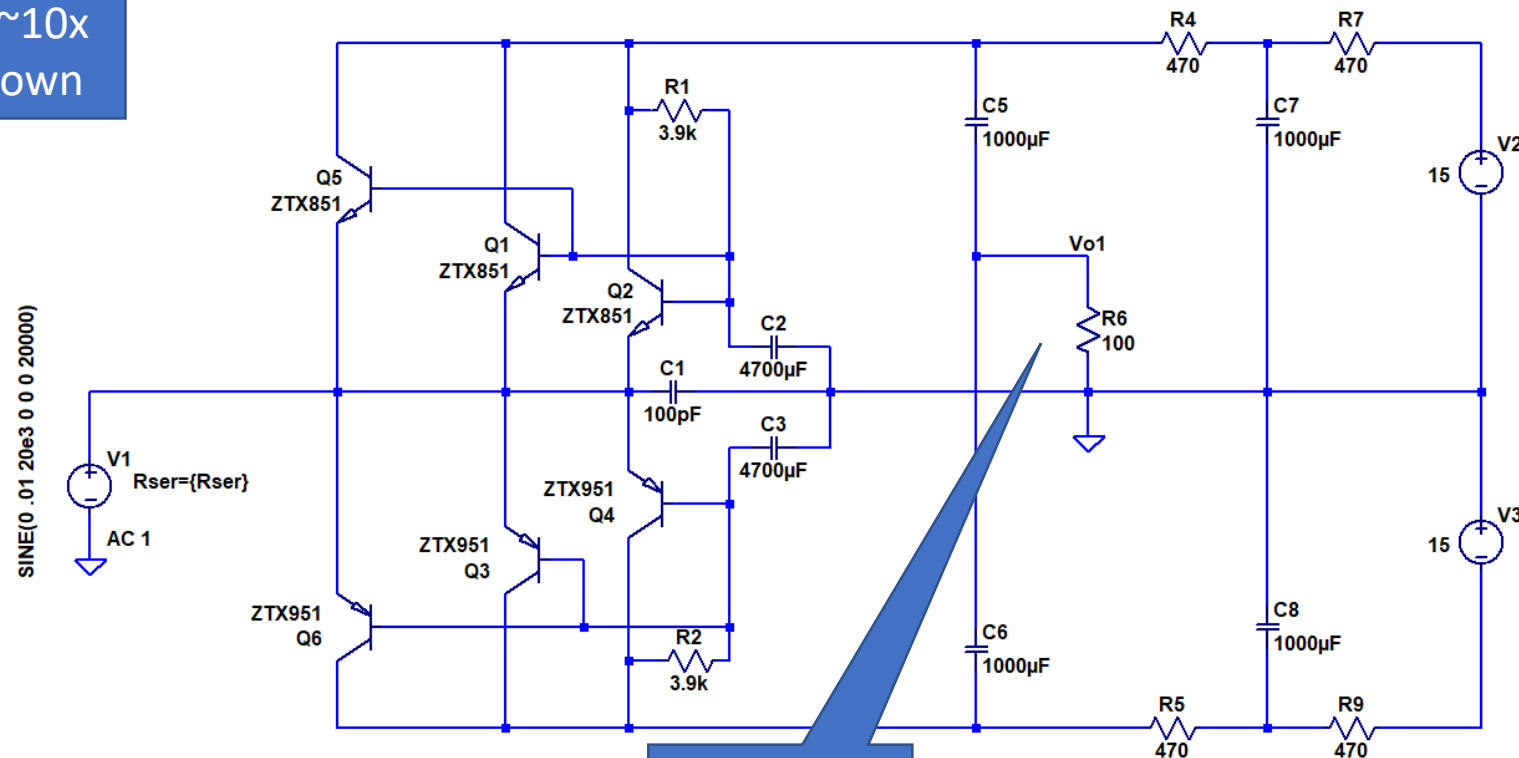
Design
developed from
the Lee/Leach
designs

Adjust gain by
adjusting this resistor.
For the values shown,
the gain is 14x (5 Ohm
Rg)

Weinberg Paralleled Complementary MC Phono Pre - 322/460 pico V/rt Hz

15mA current draw per rail; distortion .035%; gain varies with generator resistance

AV = ~10x
as shown



Adjust the
value of R6
to change
the Gain

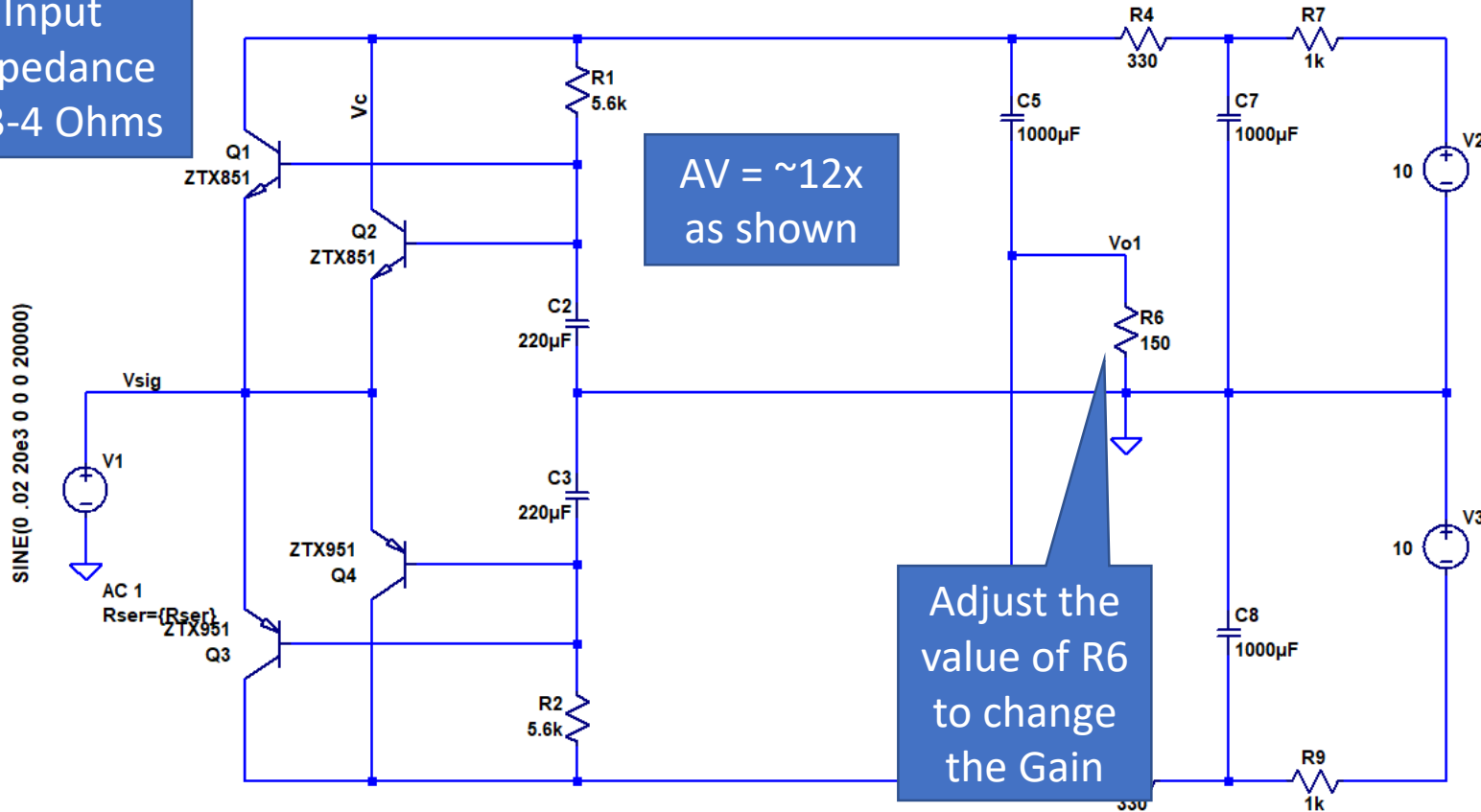
Match the transistor Vbe's to <
1mV

A challenging
design that will
require all 6
transistor Vbe's to
be matched to
within 1mV but
will yield the
lowest overall
noise. With
Rgenerator = 3
Ohms, **total** noise
is 255 pV/rt Hz

Archimedes after Richard Lee's Complementary MC Phono Pre - 353/472 pico V/rt Hz

Isupply c. 6.5mA per rail; distortion c. 0.017% @ 20kHz; 0.5~ 2MHz +0dB -3 dB;
Gain Varies with Generator coil resistance.

Input
impedance
c. 3-4 Ohms

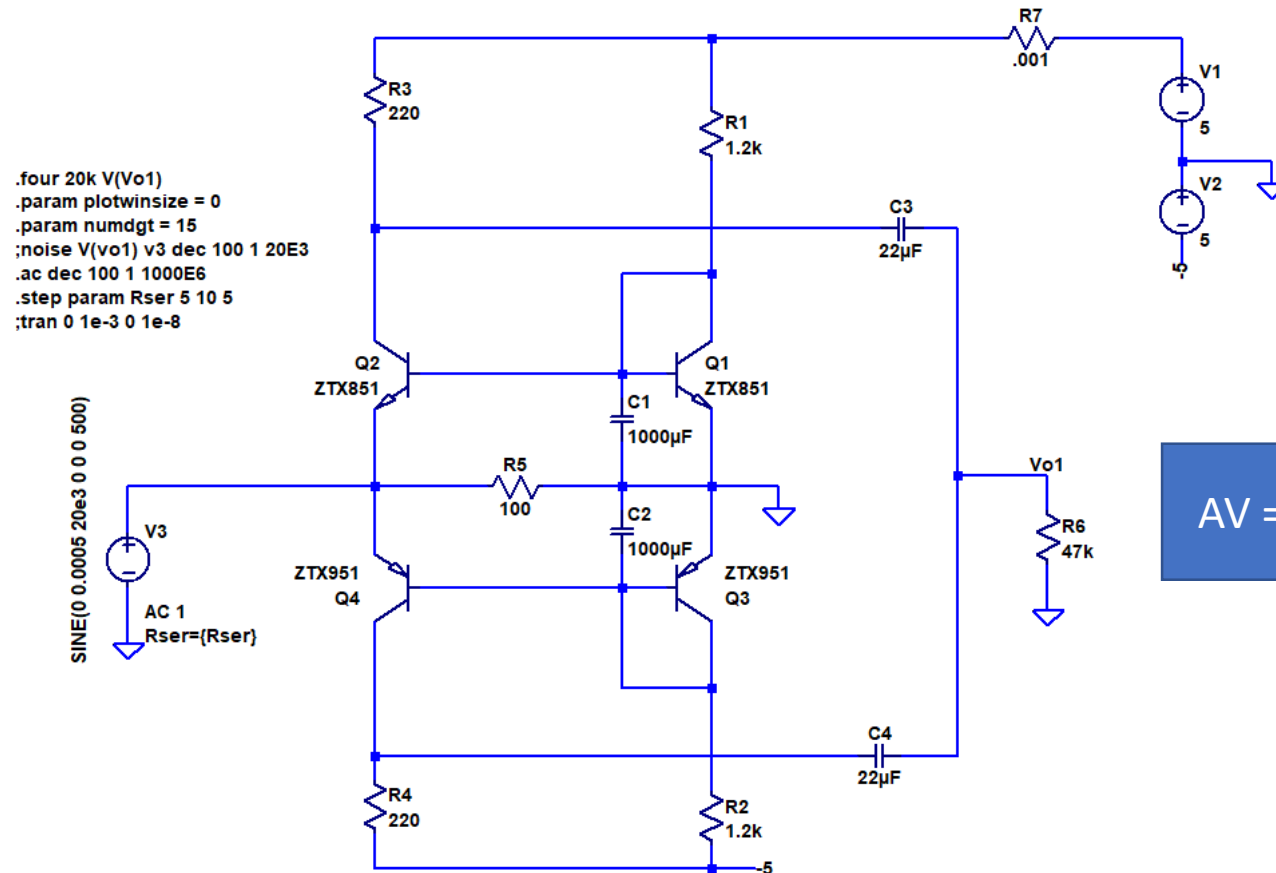


```
.four 20k V(Vo1)
.param plotwinsize = 0
.param numdgt = 15
;noise V(vo1) v1 dec 10
;ac dec 100 1 1000E6
.step param Rser 5 10
.tran 0 1e-3 0 1e-8
```

A further development of the 'Newton'. Parallel transistor pairs offer a further slight noise reduction. Amplifier only noise contribution is c. 239 pV/rt Hz and **total** noise with Rgenerator = 3 Ohms is 277 pV/rt Hz

Match the transistor Vbe's to < 1mV

Sommerfeld MC Head Amp (after Jean Hiraga); distortion 0.048/0.08% Isupply 7.5mA; noise 378/511 pico V/rt Hz



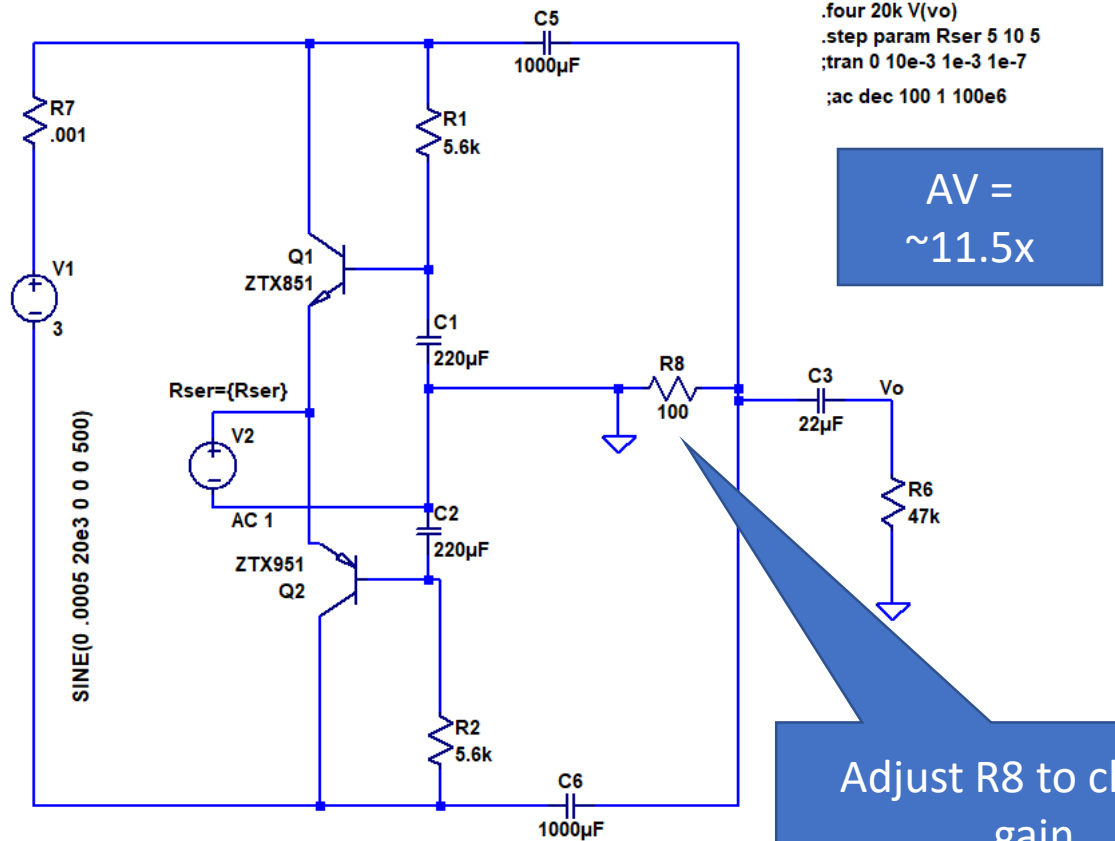
$$AV = \sim 12x$$

Another very simple circuit with good noise performance. Adjust the value of R1 & R2 for 3~4mA through R3 and R4

Adjust value of R3 and R4 to adjust gain; gain varies with generator resistance

James Chadwick MC Head Amp; 0.0002% distortion; $I_{\text{supply}} = 30\text{mA}$ 327/462 pico V/rt Hz

Gain Varies with Generator Resistance



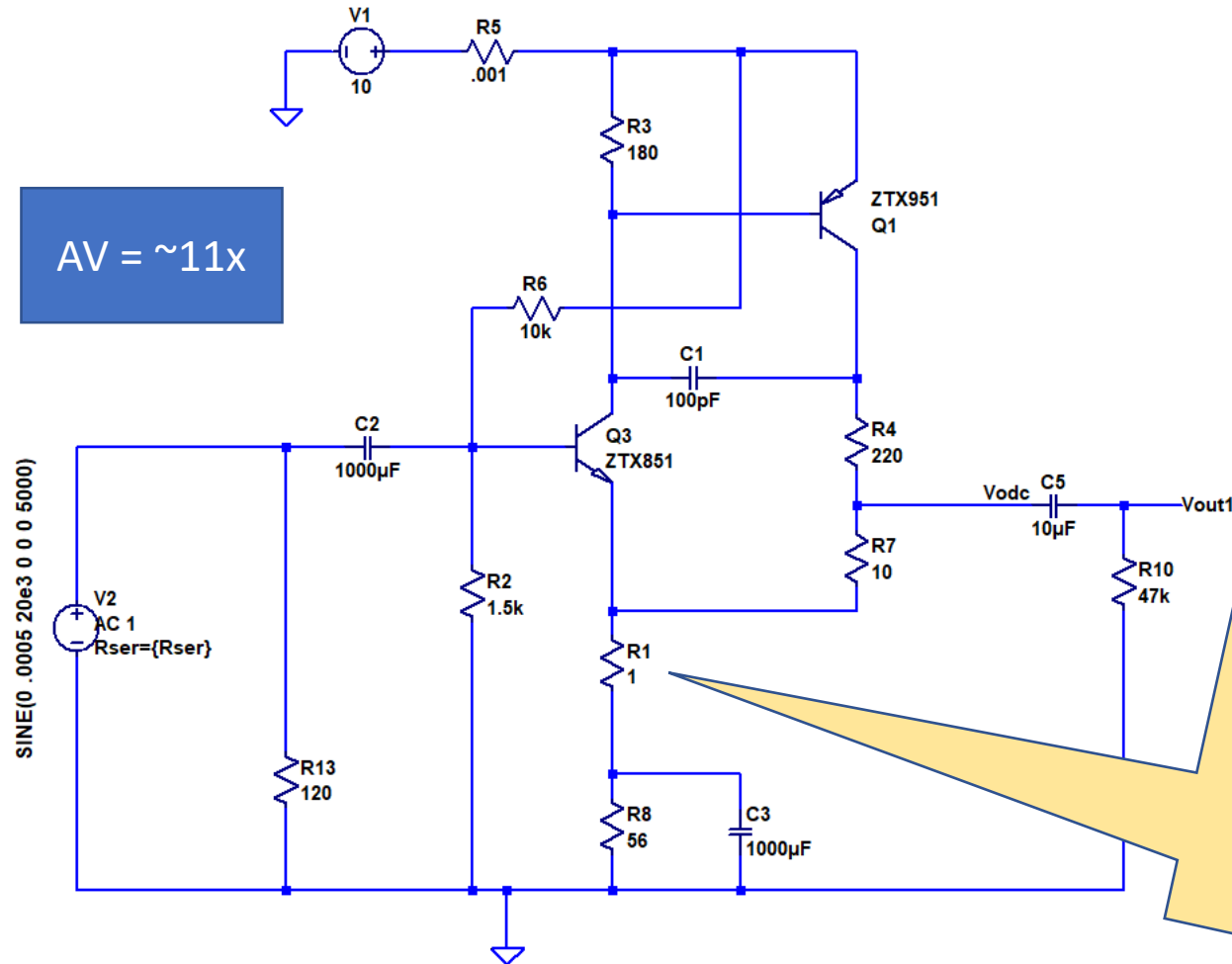
$AV =$
 $\sim 11.5x$

Adjust R8 to change
gain

3V battery
powered; Ultra
low distortion at
2ppm and
improved dynamic
range – will swing
to $\pm 0.9\text{V}$ with
 $< 0.04\%$ distortion
at 20 kHz

Bipolar Designs With Feedback

Born MC Phono pre; distortion 0.13%; Noise 460/560 pico V/rt Hz; $I_{supply} = 14mA$



```
.options plotwinsize = 0
.options numdgt = 15

.four 20k V(Vout1)
.param plotwinsize = 0
.param numdgt = 15

;ac dec 100 1 100e6
;noise V(vout1) V2 dec 100 1 100e3
.step param Rser 5 10 5

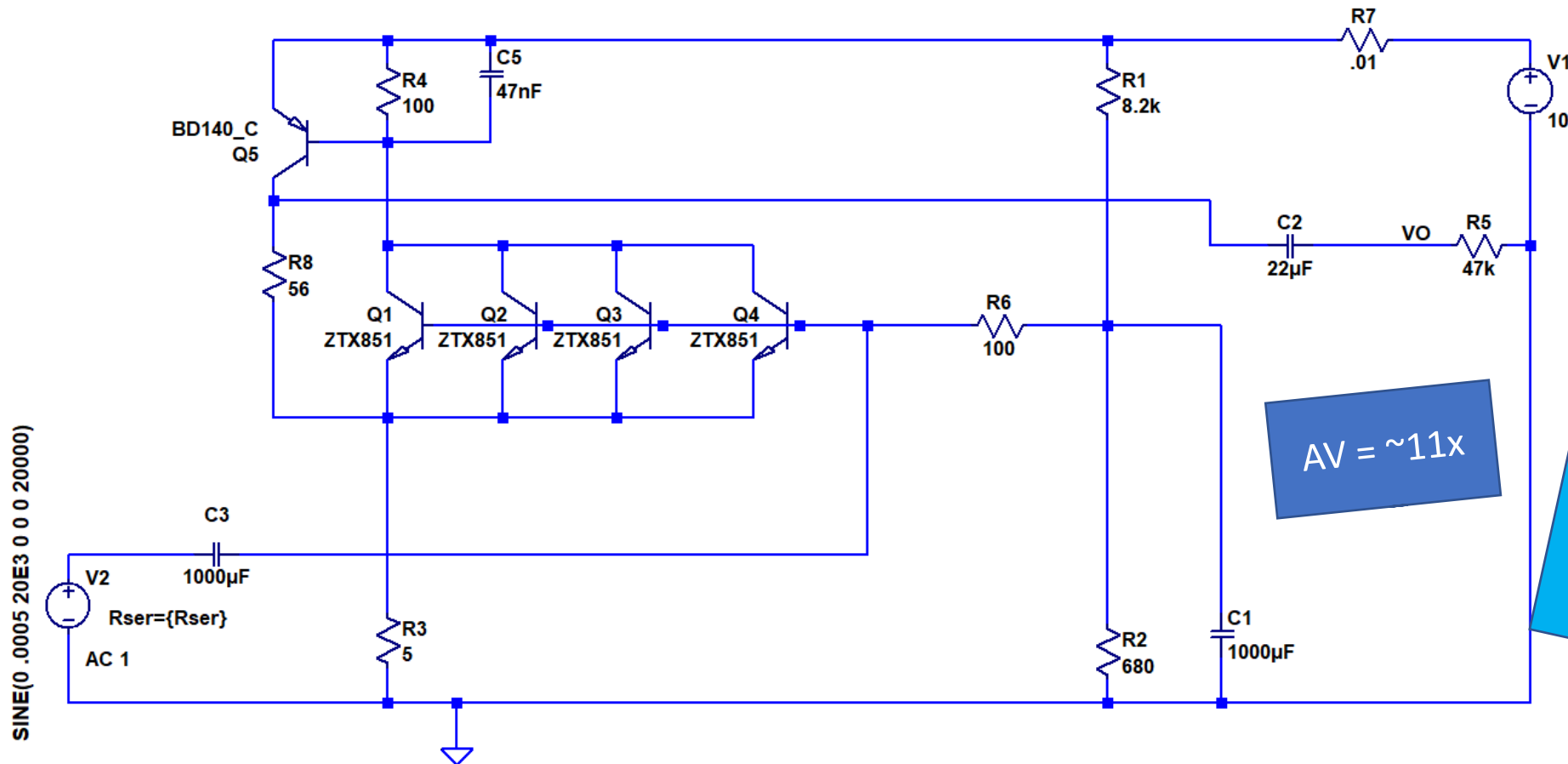
.tran 0 1e-3 100e-6 1e-8
```

Simple with good performance.

In all of these simple designs with emitter (or source) feedback, the amplifier noise is usually dominated by this resistor.

'Feynman' MC Pre; 0.01% distortion; $I_{supply} = 44mA$; noise = 489/590 pV/rt Hz; -1 dB at 20 Hz

The gain varies with generator coil resistance. Distortion is primarily 2nds with a bit of 3rds

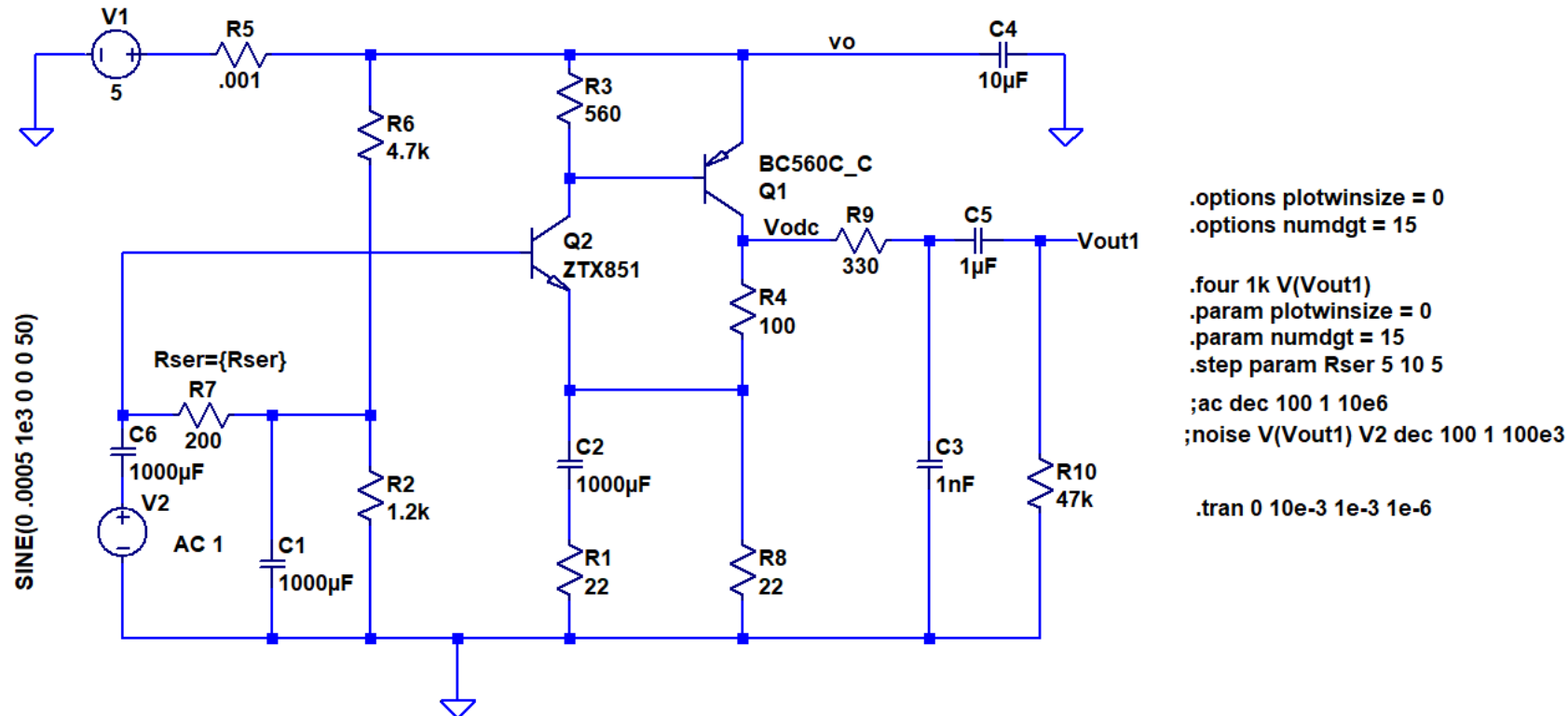


$A_V \approx 11x$

Simple, low distortion design with good noise performance; Match Q1 to Q4 Vbe's to within 1mV

Rutherford - JLH 1969 MC Pre. Noise 758/833 pico V/rt Hz; Isupply = 22mA/channel; Distortion 0.005%

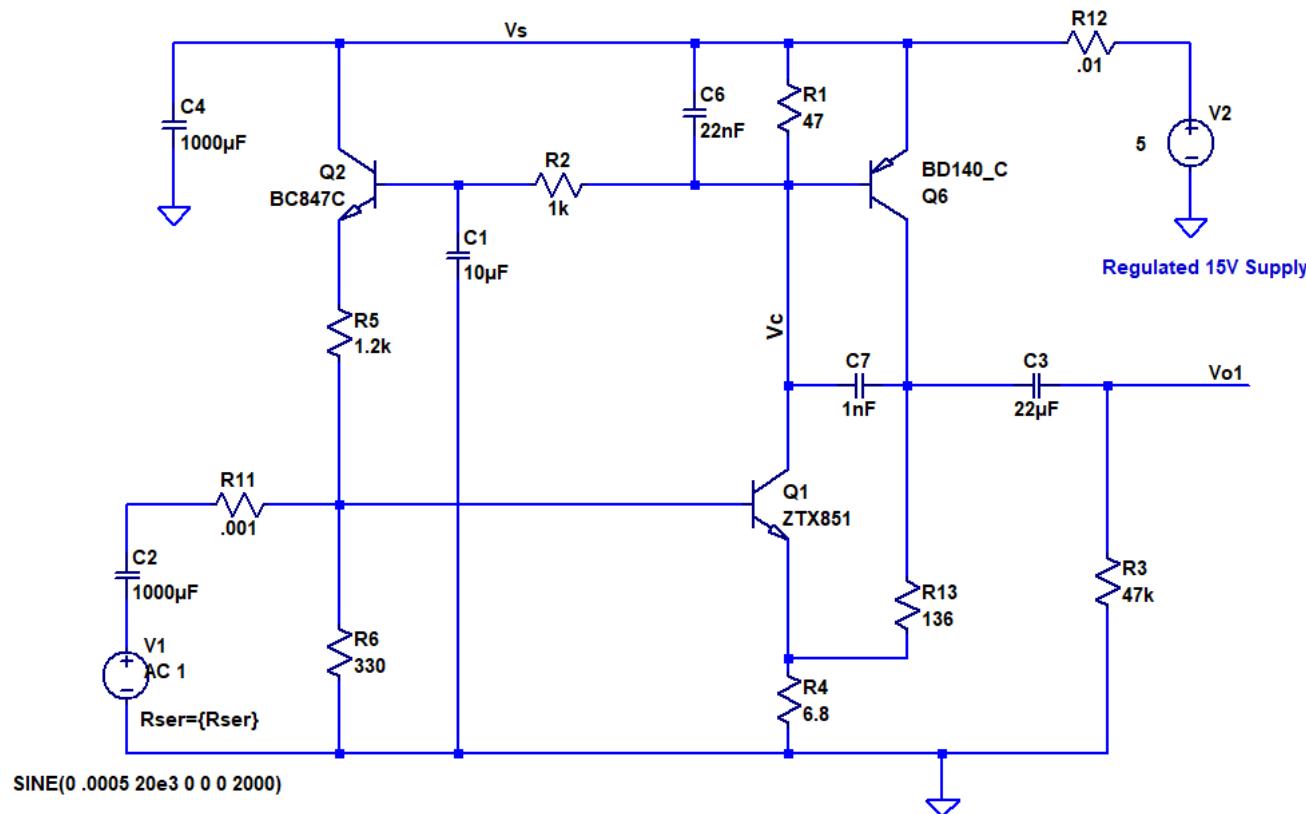
Design modified with lower R4, R8 and R1 to get lower noise; current consumption 6mA > 22mA per channel



Simple,
conventional
low noise
amplifier with
good
performance

Boltzmann Low Noise MC preamplifier 526/612 pico V/rt Hz

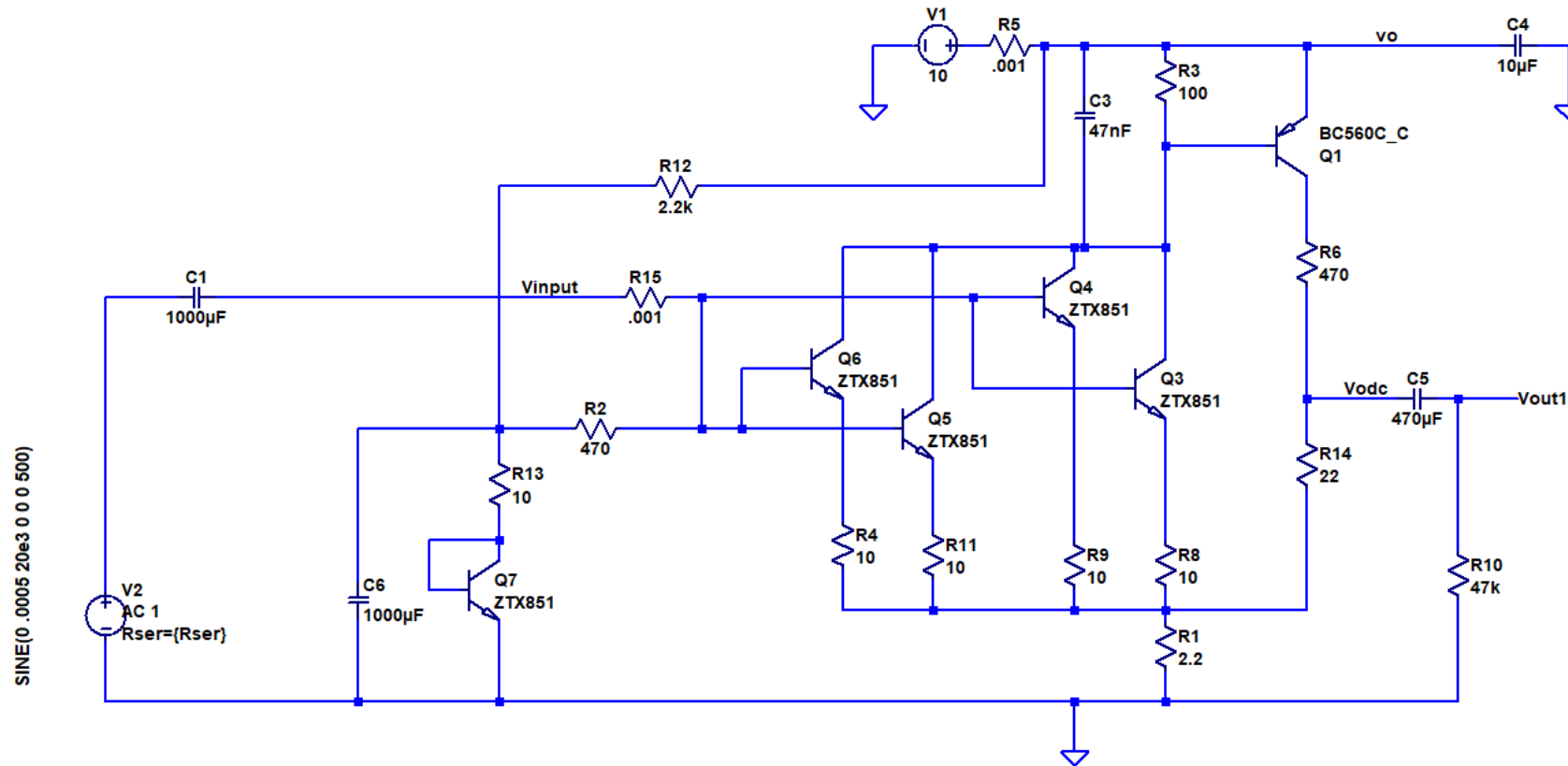
1/f corner < 10 Hz; current draw c. 28mA per channel; distortion c. 0.008% @ 20kHz; 2Hz to 2MHz +0dB -3 dB; developed from a design based on a mic pre from AoE - Horowitz and Hill page 506 3rd Ed;



Q1 can be paralleled for lower noise but requires accurate Vbe matching to <1mV across all the devices; Adjust R1 accordingly

'Kip Thorne' MC Phono Pre; distortion 0.07%; Isupply = 24mA/channel Noise = 490/570 pico V/rt Hz

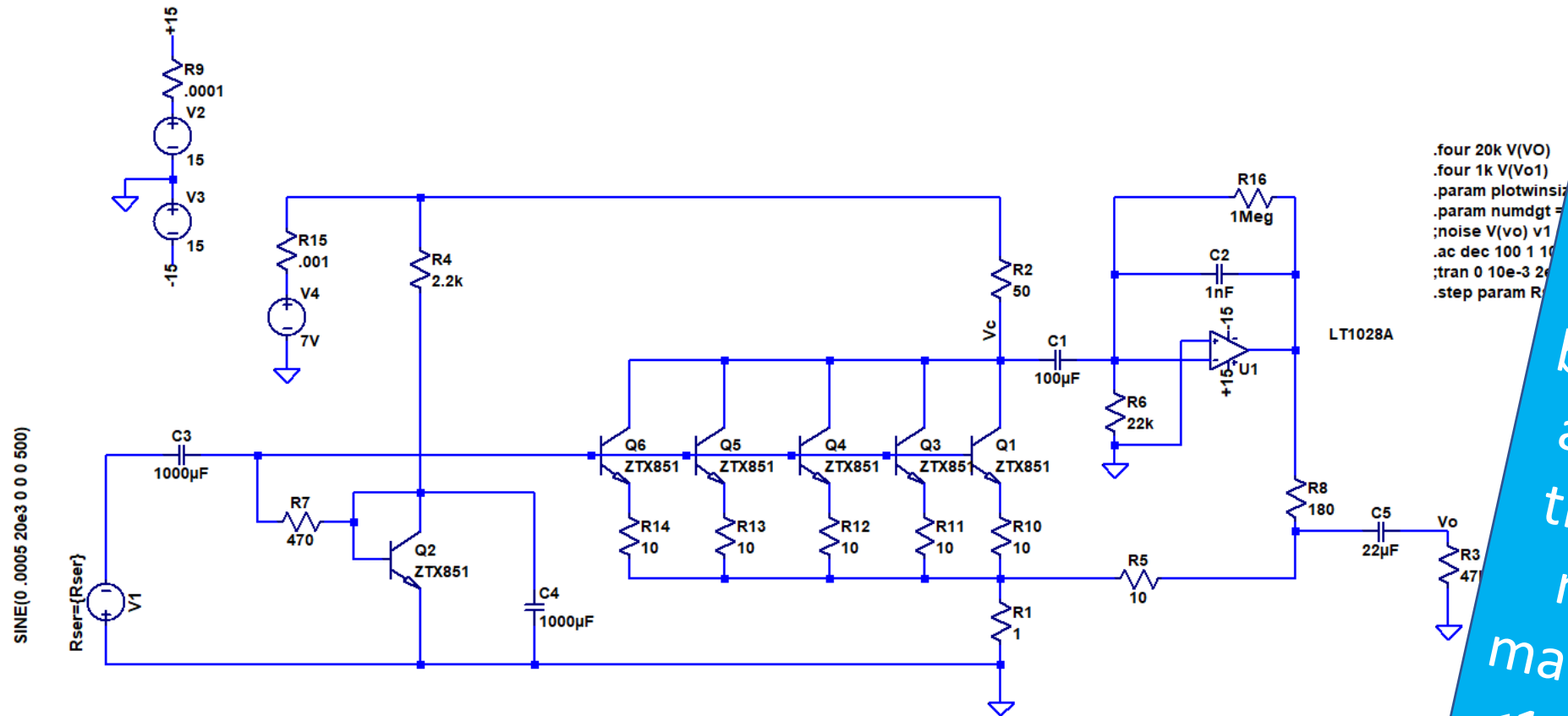
A 10% improvement in noise is possible by omitting input transistor emitter
degen resistors but then V_{be} must be matched to $< 1\text{mV}$



Adjust R12
and/or R13 to
change the
amplifier
transistor
collector current
to optimize
noise for the
cartridge DC
resistance.

The 'DeBroglie' MC Head Amp; noise $\sim 470/560$ pico V/rt Hz; distortion ~ 70 ppm Isupply 10mA EXCLUDING the opamp; Adjust R4 for 5mA through R2

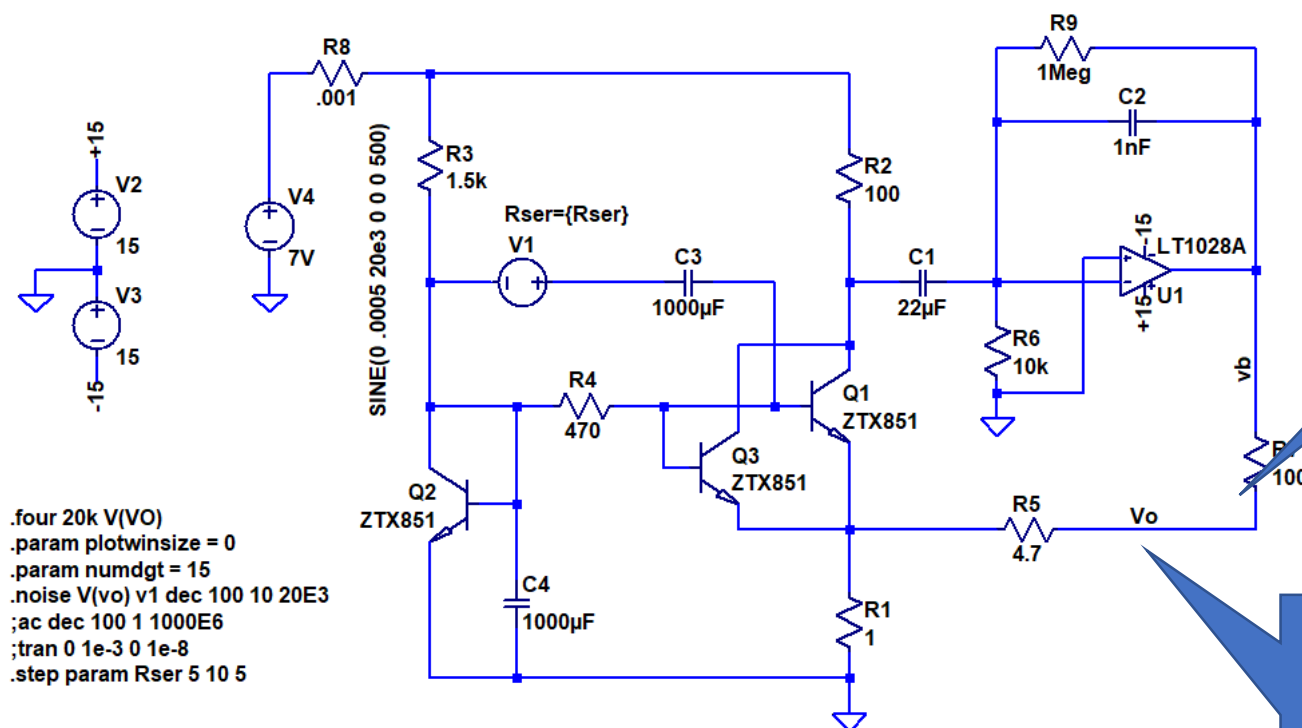
Match the Vbe of Q1, Q3-Q6 to better than 1mV if omitting R10-R14. The transistor Ic deltas will then be $\sim 60\mu\text{A}$ per mV difference in Vbe



Lower
amplifier
only noise is
possible by
omitting
R10~R14
but Vbe's of
associated
transistors
must be
matched for
<1mV dVbe

The Heisenberg Low Noise MC-HA; distortion 13 ppm; noise 408/504 pico Volts/rt Hz Isupply 10mA excl. opamp

! ATTENTION: Match Q1 and Q3 Vbe to within 1mV



AV = ~15x

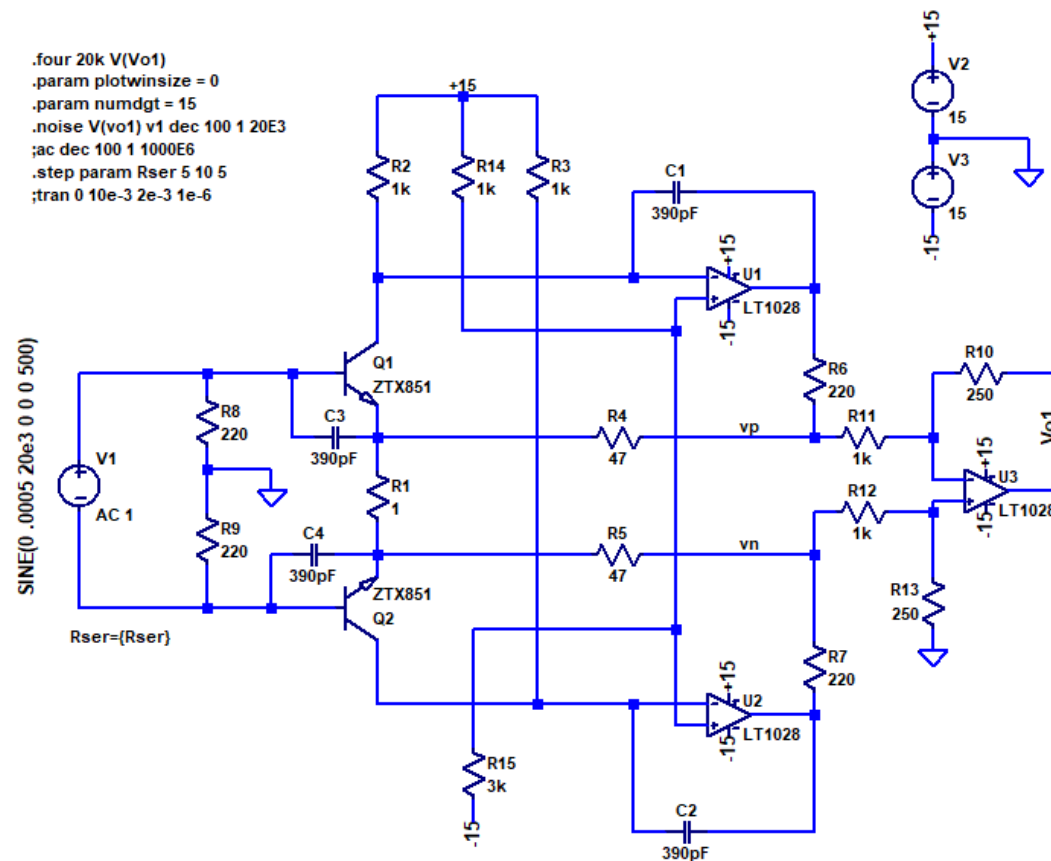
With R5 = 0 Ohms,
gain is ~11x and noise
improves to 386/487
pico V/rt Hz

Adjust the
value of R3 to
change the
collector
current of Q1
and Q3 to
optimize noise
to cartridge;
match Q1 &
Q2 dVbe to <
1mV

J J Thompson MC Head Amp; 480/570 pico V/rt Hz; distortion 0.0017%; DC - 500kHz -3dB

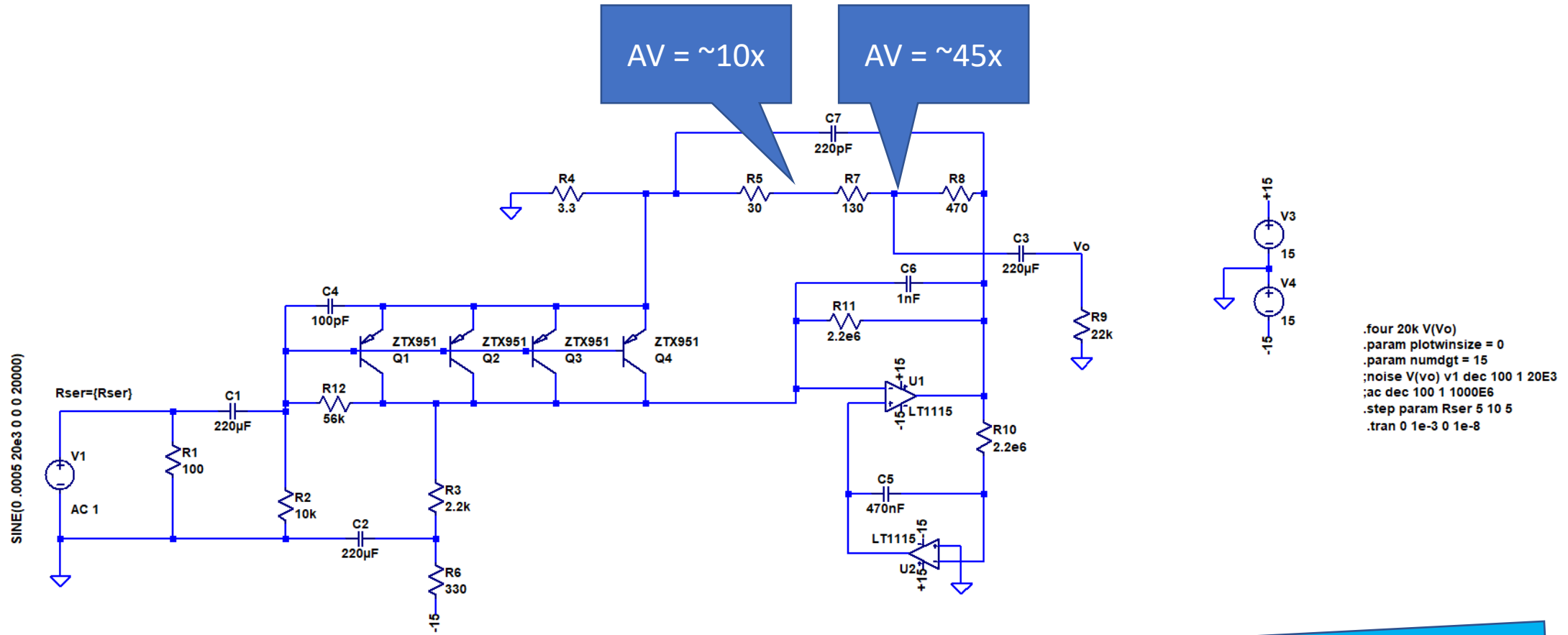
From an idea originally published by Robert Demrow,
Analog Devices Inc, 1968 plus work done by W. Kirkwood, 2017

Requires further work to optimize the compensation and frequency response



Very high
performance MC
head amp; low
noise plus added
benefit of
balanced input;
R1, R4 and R5 set
gain; tightly
match ALL
resistors for best
performance

**'Fermi' 459/565 pico Volts/rt Hz ; Isupply c. 20mA; distortion 0.01%
From Rod Elliot site based on a Douglas Self design.**

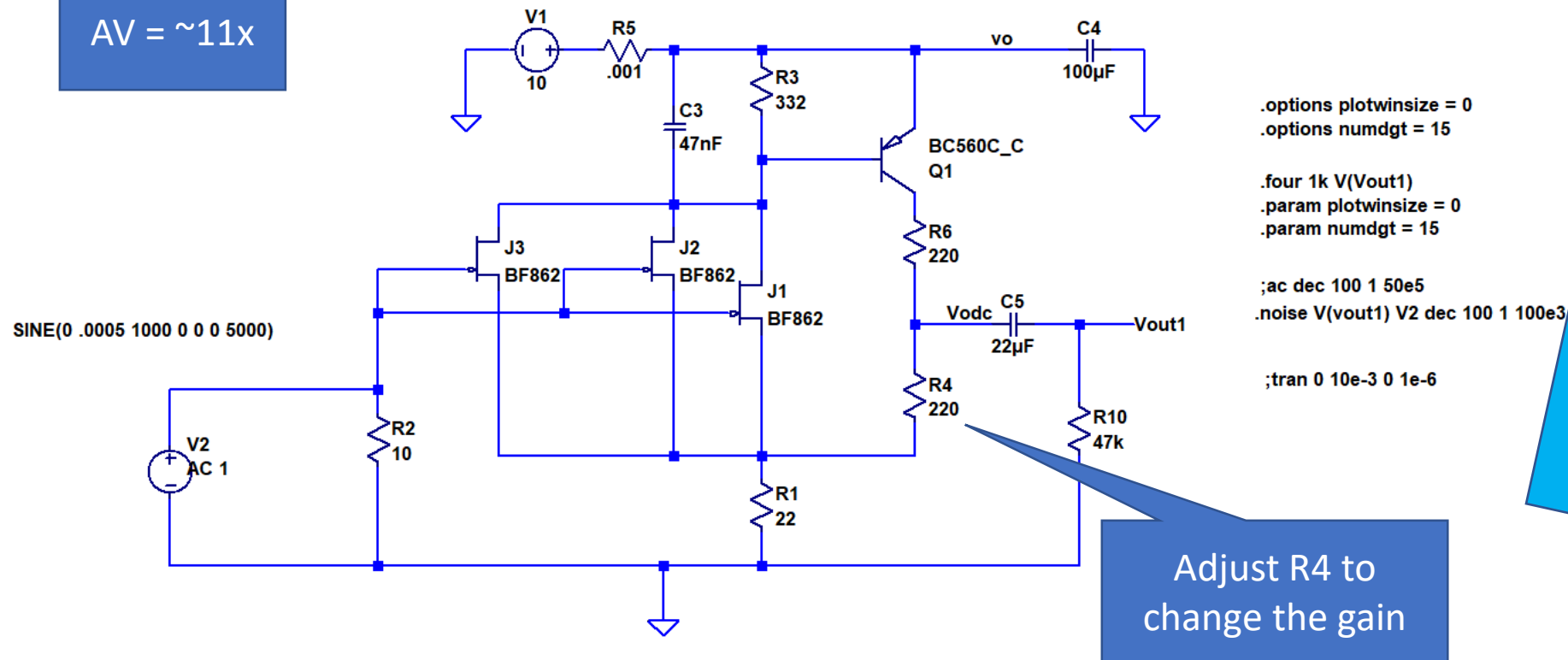


Complex but performance is good. Match Q1-Q4 Vbe for best performance to within 1mV. Adjust C6 to optimize loop and frequency response.

JFET Input Designs

Dirac JFET MC Phono; 1.1nV/rt Hz; Isupply = 17mA Distortion 13ppm; 1/f noise corner of ~100 Hz

AV = ~11x



Use ferrite beads in each of the JFET gates to prevent possible HF parasitic oscillation

Faraday JFET MC Head Amp; distortion ~15 ppm; current consumption 8mA; noise 1.3/1.4 nV/rt Hz

```
.options plotwinsize = 0
.options numdgt = 15

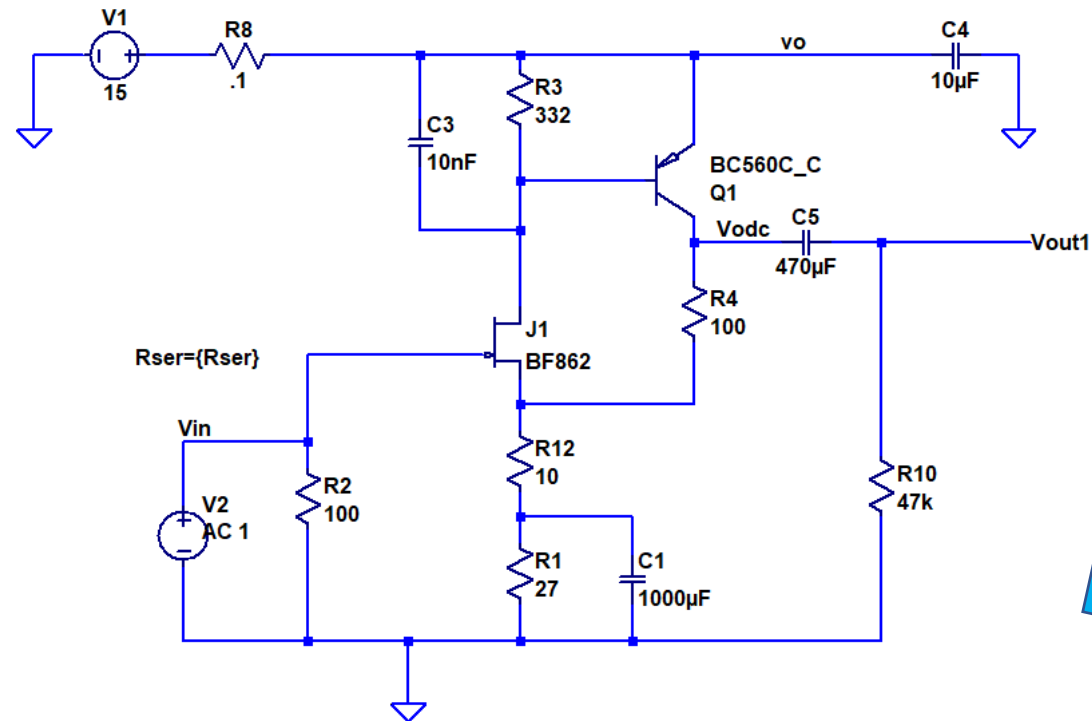
.four 20k V(Vout1)
.param plotwinsize = 0
.param numdgt = 15

;ac dec 100 1 20e3
.noise V(vout1) v2 dec 100 1 20e3

;tran 0 1e-3 0 1e-8

SINE(0 .0005 20e3 0 0 0 500)

.step param Rser 5 10 5
```



Nice and simple
with low
distortion; suits
MC carts with >
20 Ohms coil
resistance

Galileo JFET MC Head Amp; distortion ~15 ppm; current consumption 13mA; noise 1.5/1.6 nV/rt Hz

```
.options plotwinsize = 0
.options numdgt = 15

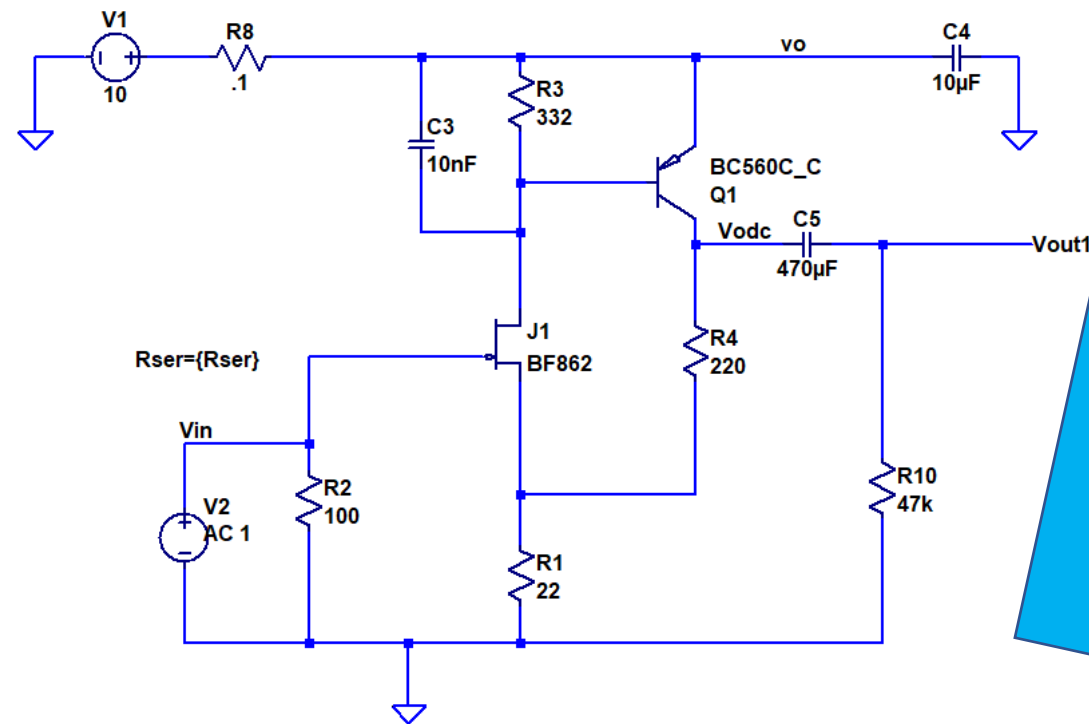
.four 20k V(Vout1)
.param plotwinsize = 0
.param numdgt = 15

;ac dec 100 1 20e3
.noise V(vout1) v2 dec 100 1 20e3

;tran 0 1e-3 0 1e-8

SINE(0 .0005 20e3 0 0 0 500)

.step param Rser 5 10 5
```



Nice and simple with low distortion and moderate noise performance. This circuit has been built and works well; suits MC cartridges with 0.5mV output and coil resistances of > 20 Ohms

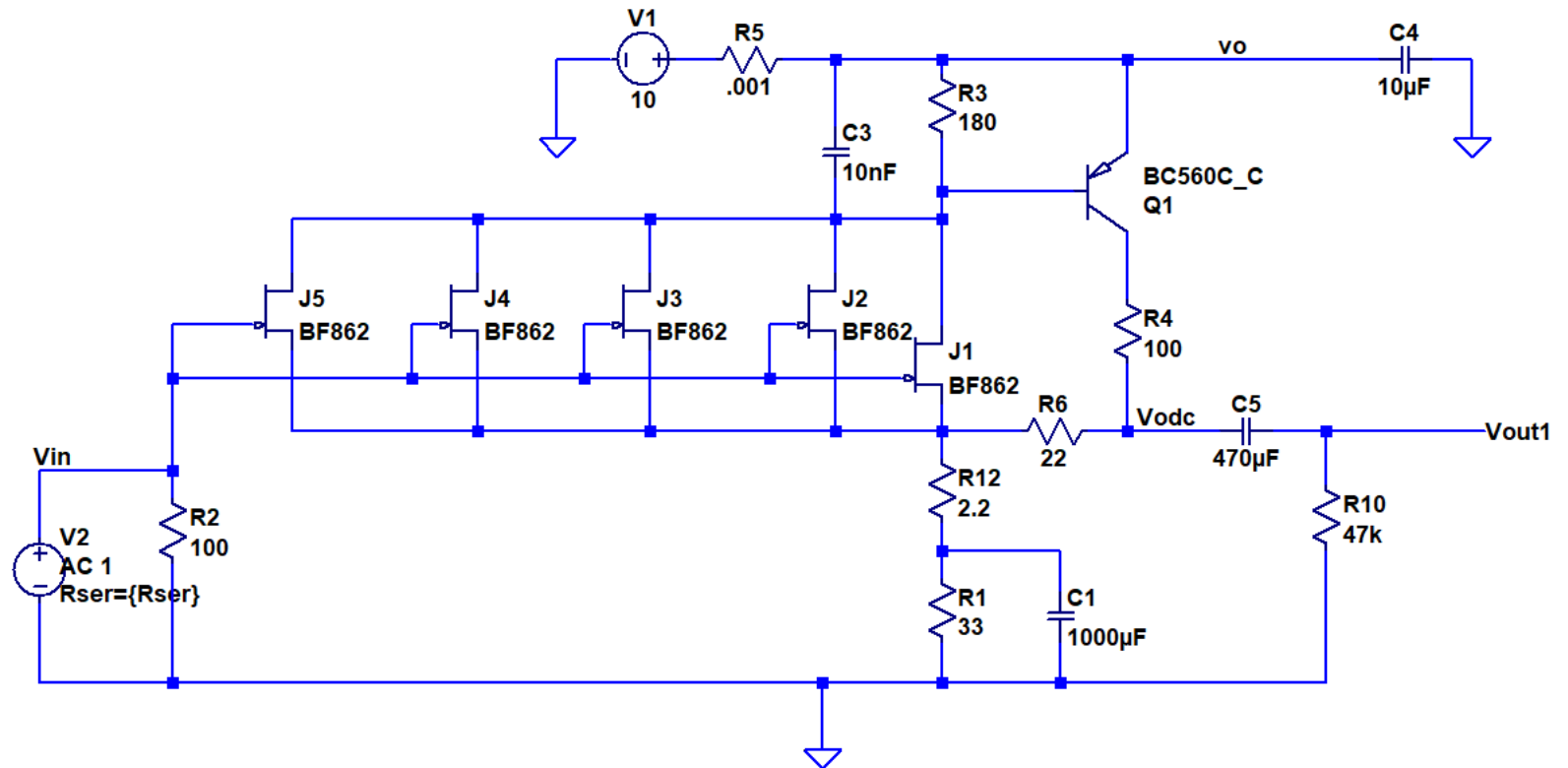
Gell-Mann MC Head Amp; distortion 0.1%; current consumption 8mA; noise 740/829 pico V/rt Hz

.options plotwinsize = 0
.options numdgt = 15

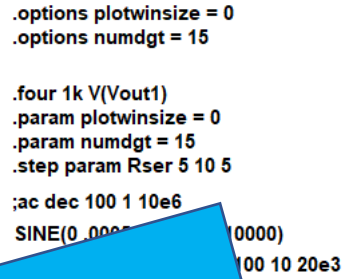
.four 20k Vp

20e3

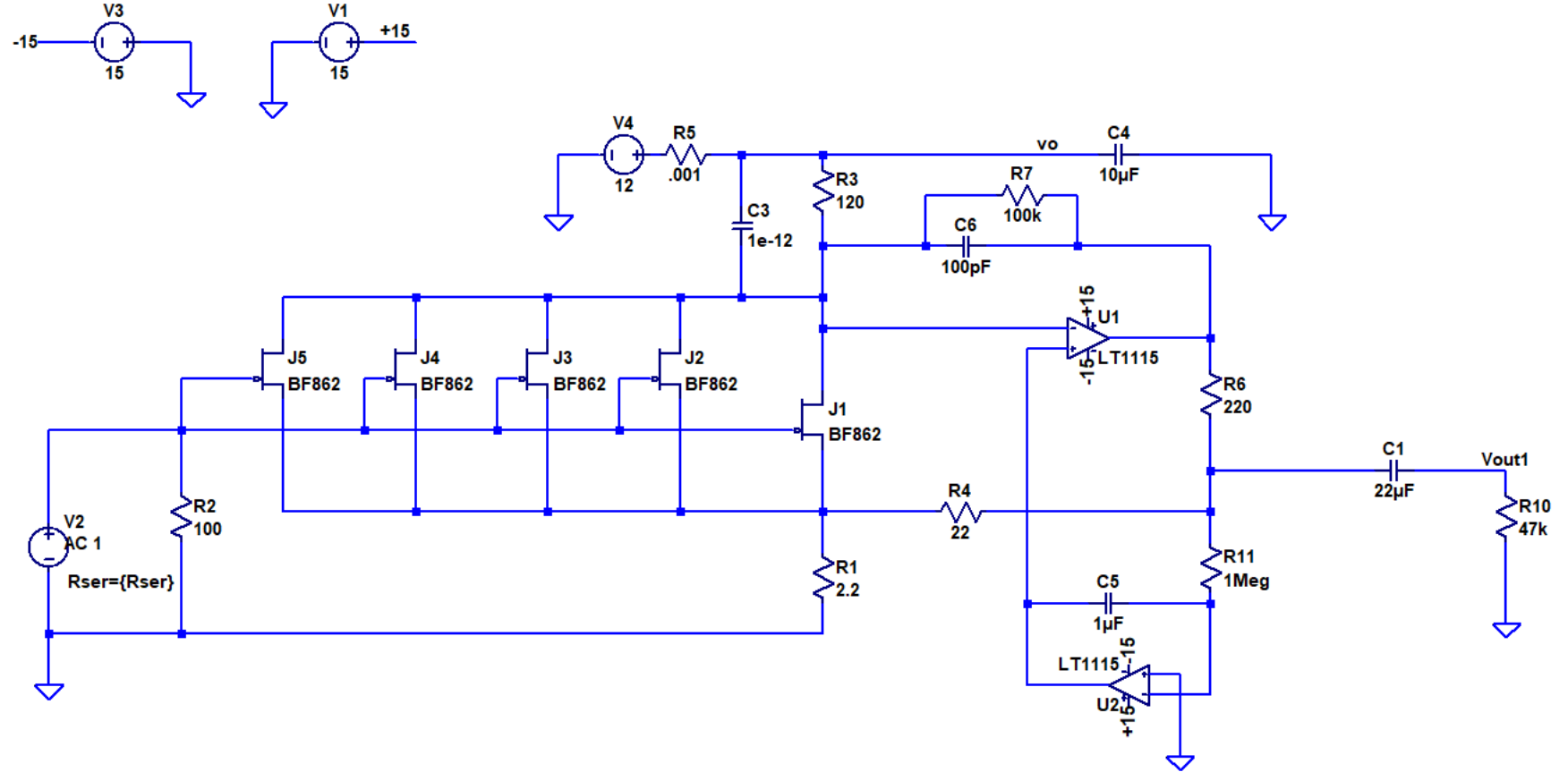
Use ferrite
beads in each of
the JFET gates
to prevent
possible HF
parasitic
oscillation



Julian Schwinger JFET MC Front end; 572/670 pico V/rt Hz; distortion ~1ppm
Current consumption ~10mA excl. the opamp

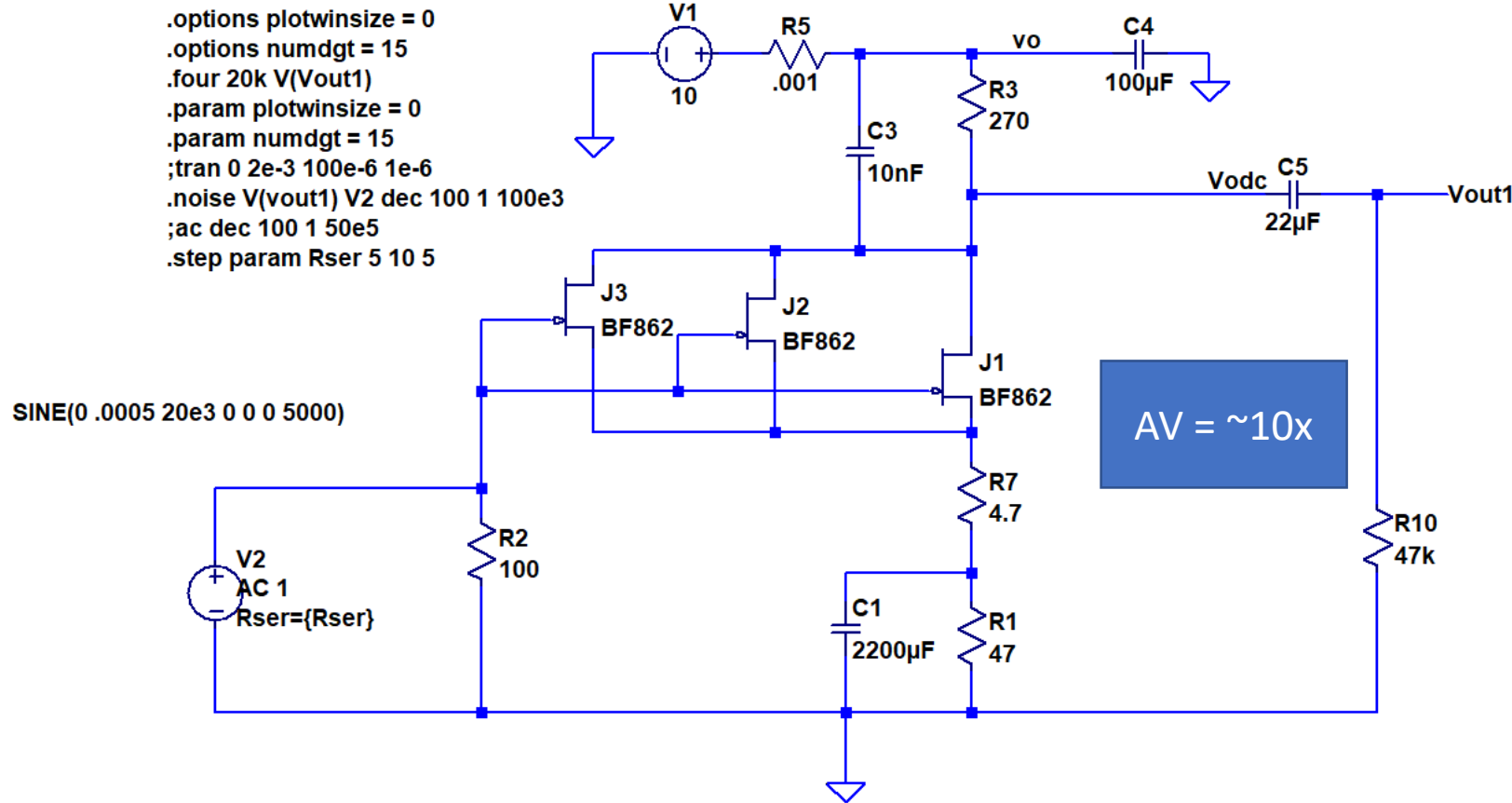


Use ferrite beads in each of the JFET gates to prevent possible HF parasitic oscillation



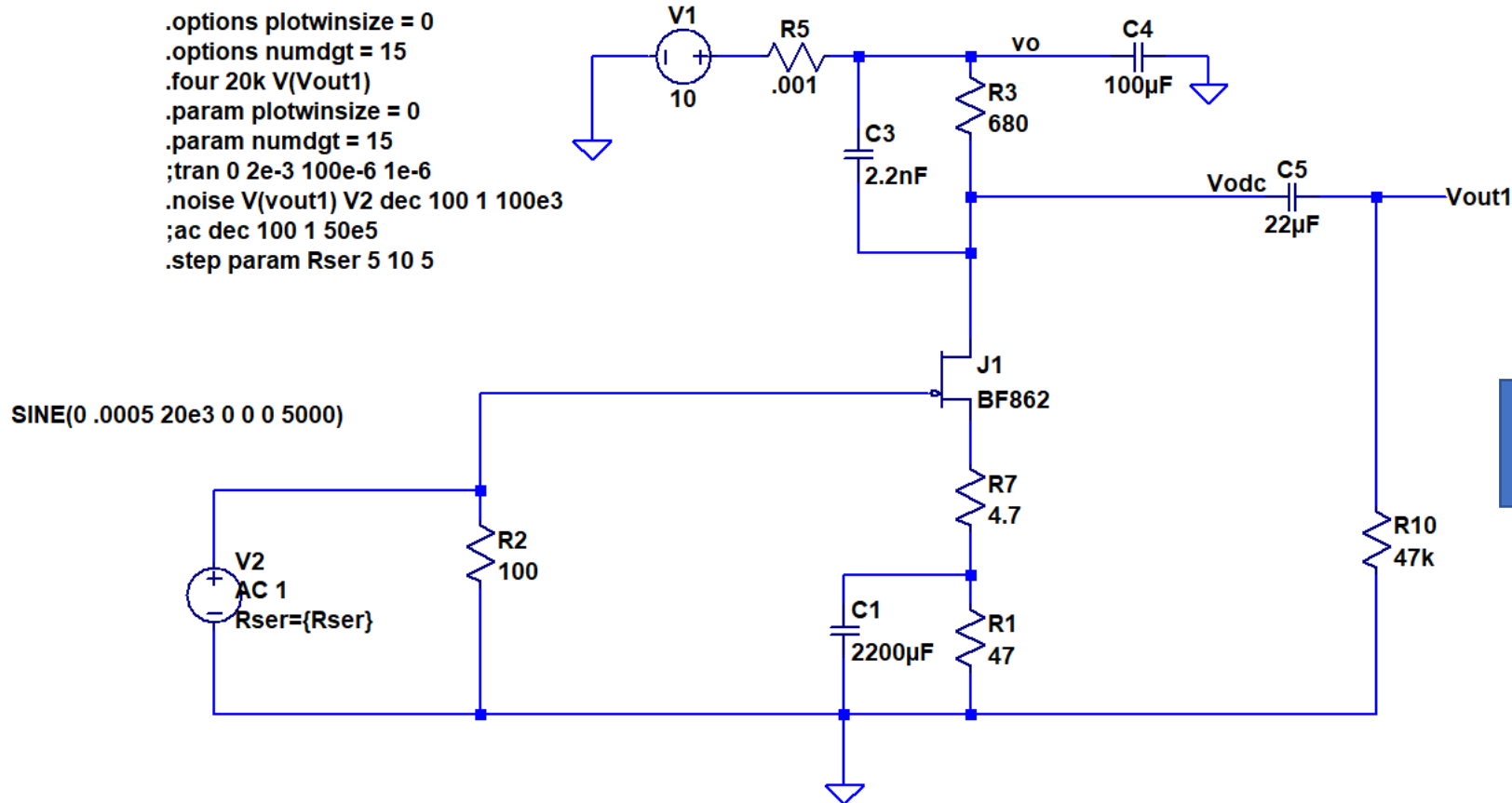
Gamow JFET MC Phono; $I_{\text{supply}} = 5.5\text{mA}$ Distortion 0.03%; 804/866 pico V/rt Hz

Simple with good performance. Use ferrite beads in each of the JFET gates to prevent parasitic HF oscillation.



Bethe simple JFET MC Phono; Isupply = 3.8mA Distortion 0.027%; 1116/1240 pico V/rt Hz

Ultra Simple JFET
MC HA



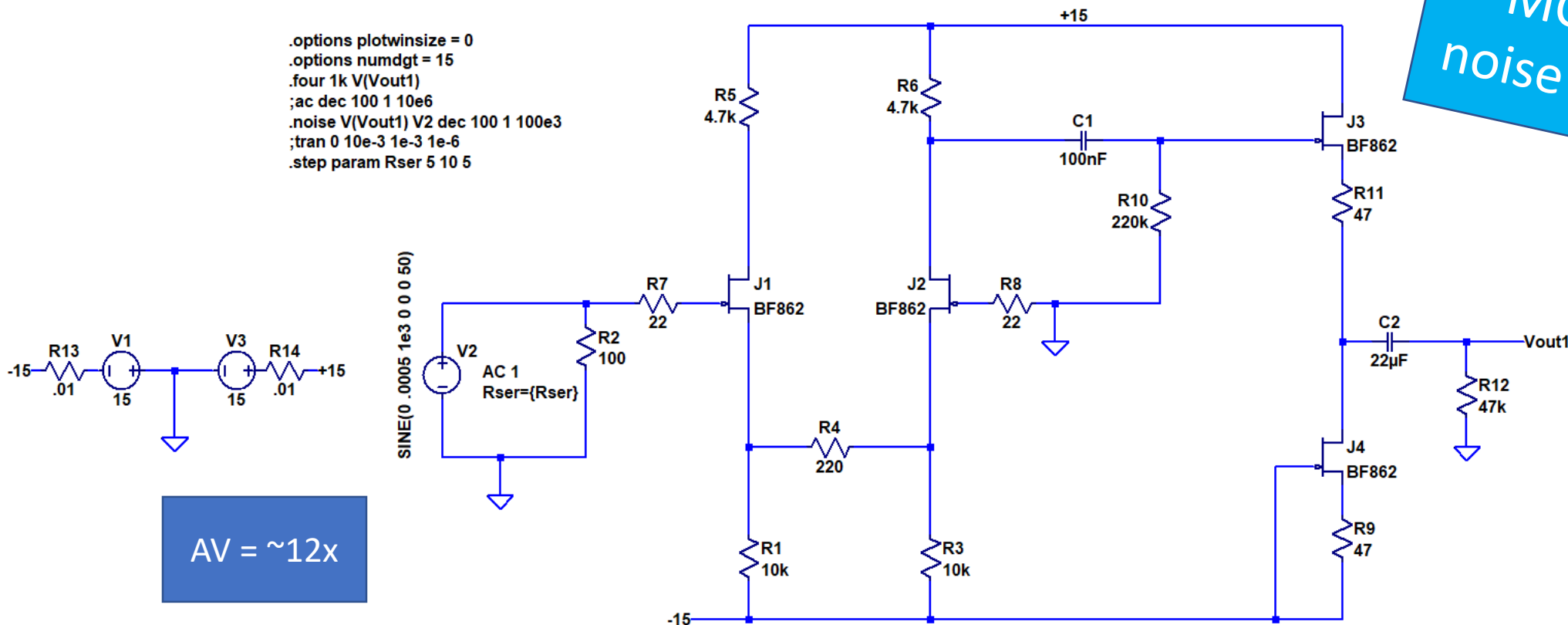
AV = ~10x

Huygens MC HA; Noise 2.9/3.1 nV/rt Hz; Isupply = 7.5mA; Distortion 0.005%

This is the Piccolo2 JFET MC HA from Hagman Audio Labs

Simple all-JFET
MC HA – but
noise is very high

```
.options plotwinsize = 0
.options numdgt = 15
.four 1k V(Vout1)
;ac dec 100 1 10e6
.noise V(Vout1) V2 dec 100 1 100e3
;tran 0 10e-3 1e-3 1e-6
.step param Rser 5 10 5
```



AV = ~12x

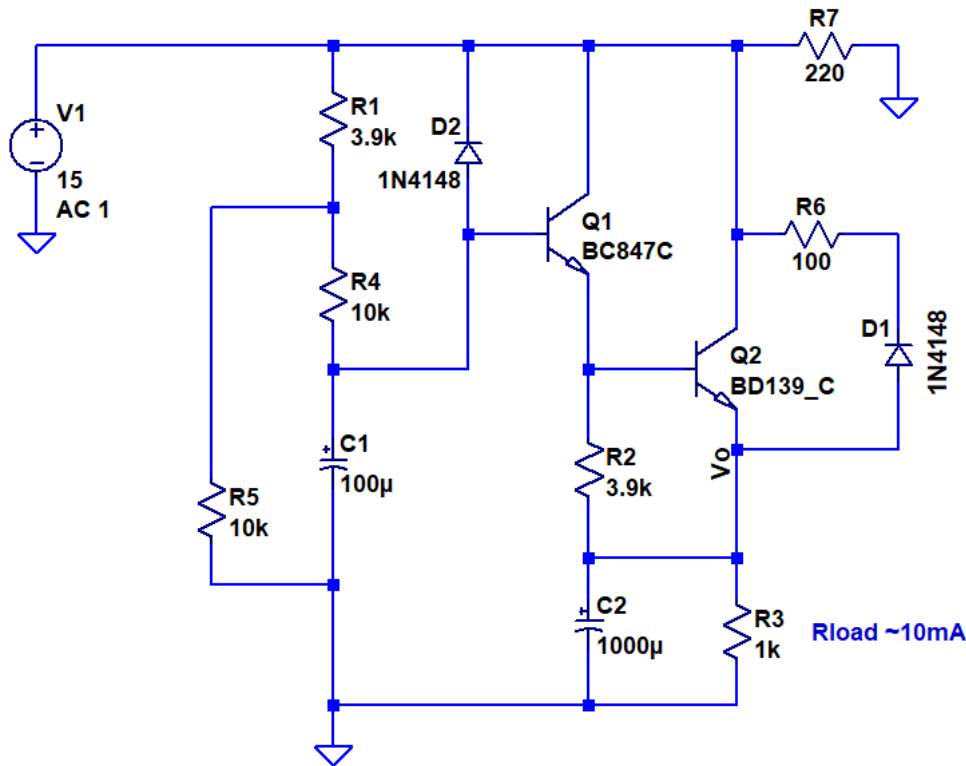
Simple low noise PSU's that can be used with the MC Head Amps.

These circuits would need to be very carefully laid out and well executed to approach the simulated performance. On the opamp based versions, practical circuits would likely need some further work on the loop compensation.

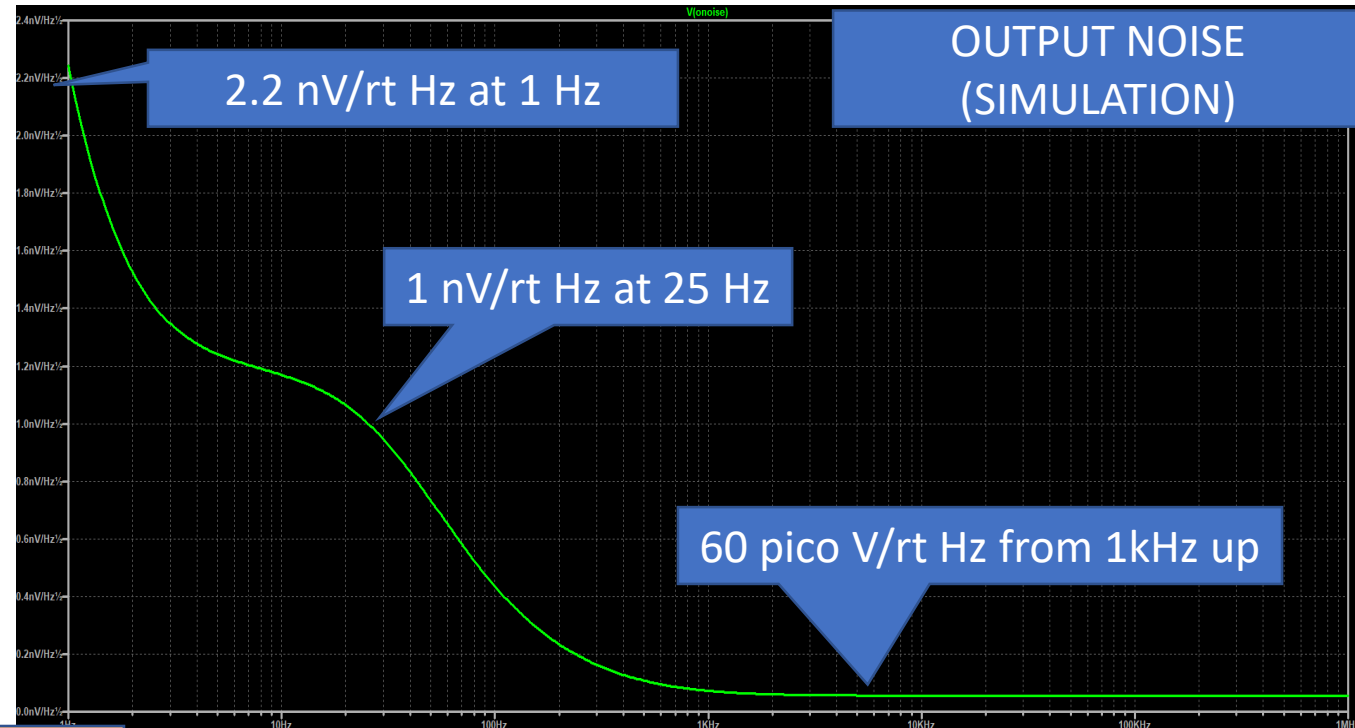
Bohr - Simple cap multiplier PSU for MC Head Amp

Capacitor ESR - and especially C2 - put a lower limit on the noise of this circuit. For the cap shown with an ESR of 120mOhms, it is about 60 pico V/rt Hz. C2 should be a low ESR type, or made up of a number of low ESR types in parallel. D1 allows C2 to discharge quickly as does D2 for C1

For the values of R1 and R5 shown, the output voltage is 9.5V. Adjust accordingly for other output voltages. The upper limit of this circuit with a 15V input supply is about 10V.



```
;noise V(vo) V1 dec 100 1 1e6  
.tran 0 1e-3 0 1e-6
```



Marie Curie Low Noise 10mA Power Supply

10V output at c. 10mA; PSRR 40 db/Decade 1Hz to 1kHz, thereafter c 120dB to 1MHz.

As with Bohr PSU, ESR of C3 is critical. For the 47mOhm device shown, noise is about 30 pico V/rt Hz from 200 Hz and above

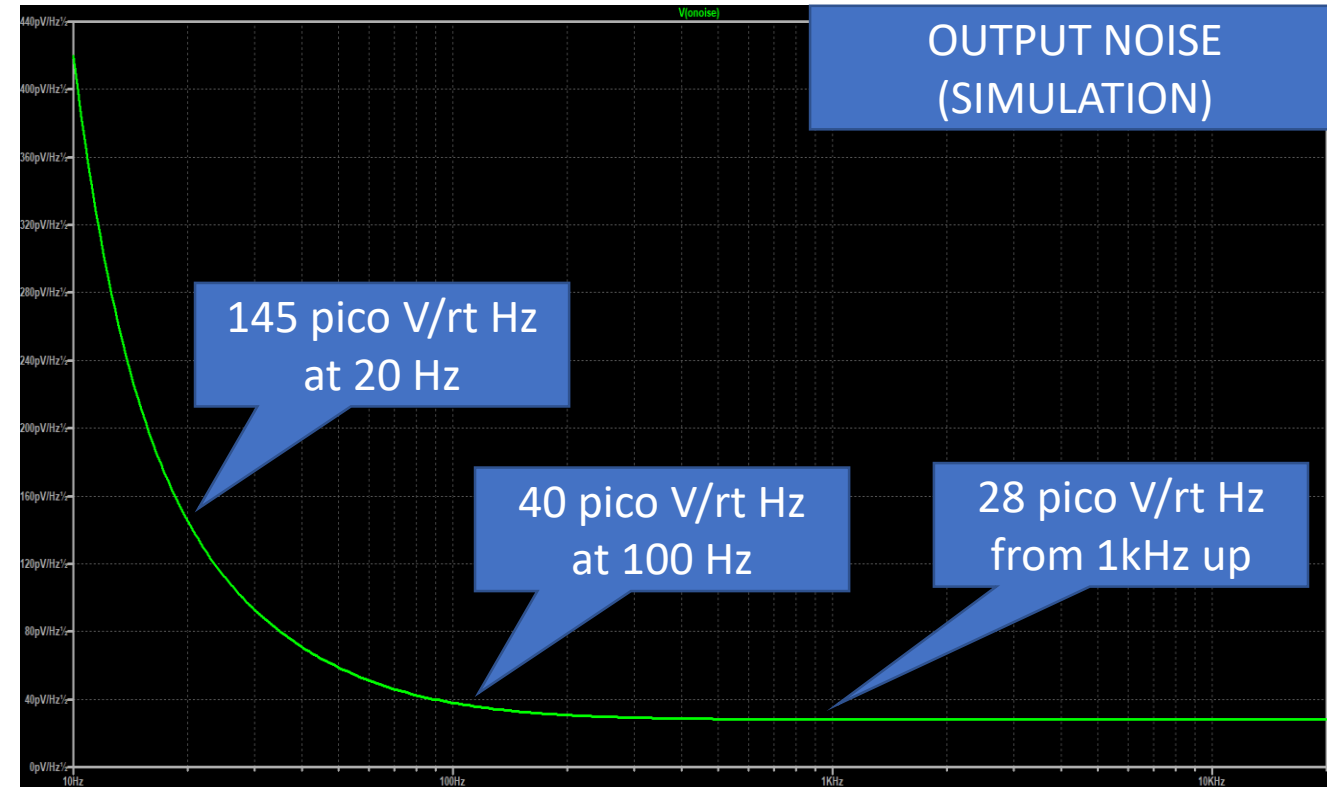
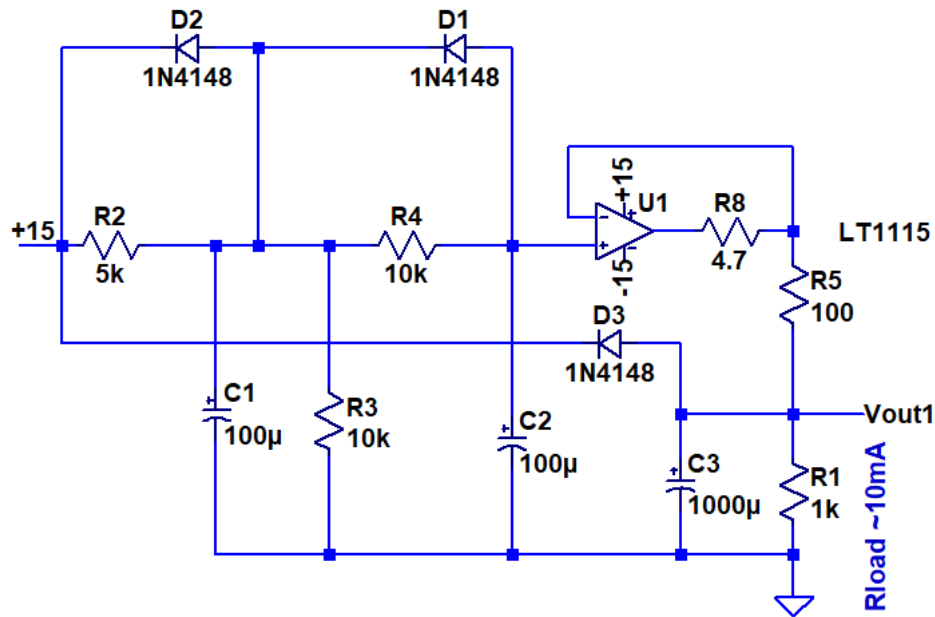
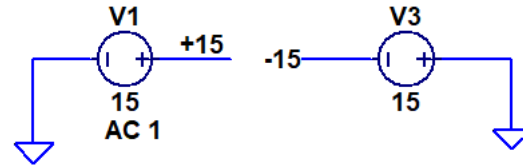
```
.options plotwinsize = 0
```

```
.options numdgt = 15
```

```
.ac dec 100 1 10e6
```

```
;tran 0 10e-3 1e-3 1e-6
```

```
;noise V(vout1) V1 dec 100 10 20e3
```

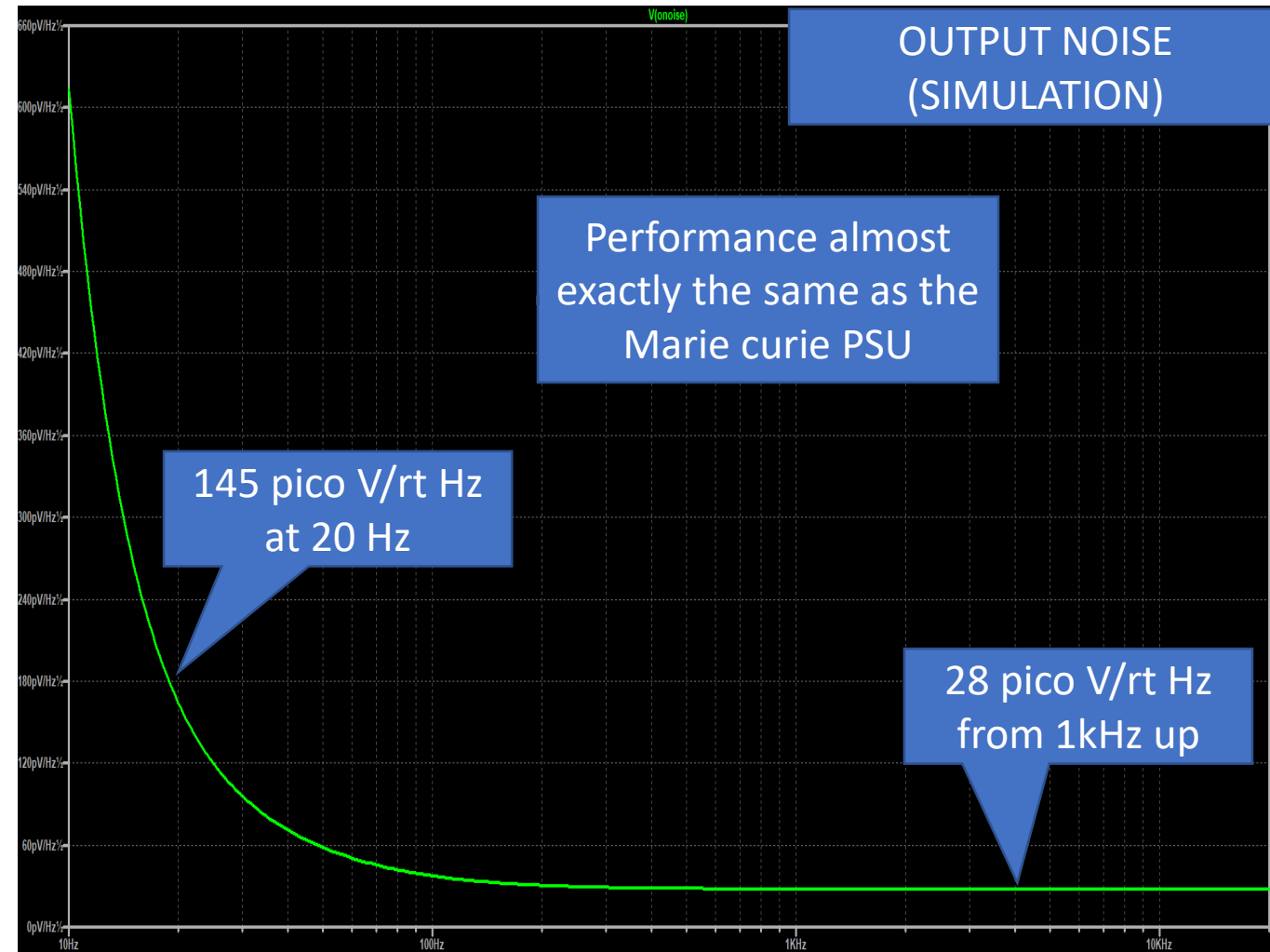
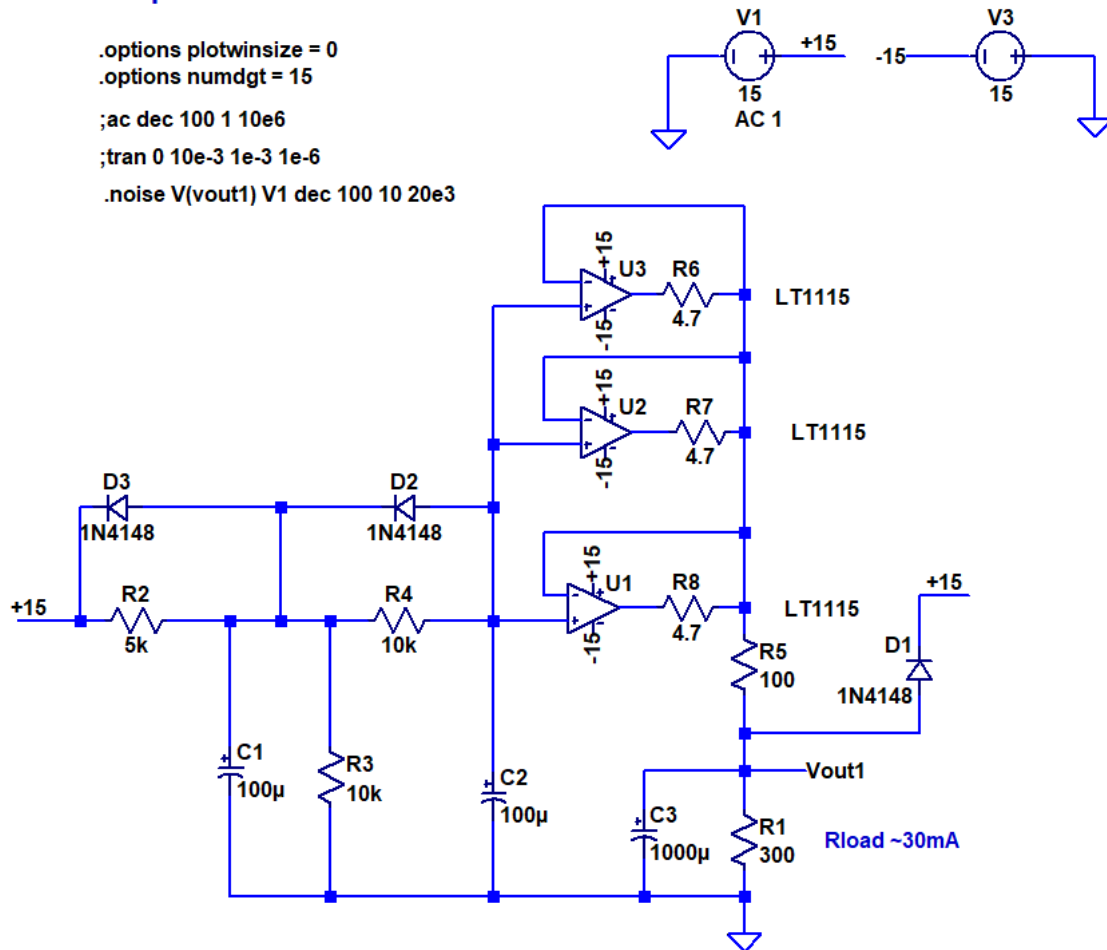


Rontgen Low Noise 30mA Power Supply

10V output at c. 30mA; PSRR 40 db/Decade 1Hz to 1kHz, thereafter c 120dB to 1MHz.

As with Bohr and Curie PSU's, ESR of C3 is critical. For the 47mOhm device shown, noise is about < 30 pico V/rt Hz from 200 Hz and above

```
.options plotwinsize = 0
.options numdgt = 15
;ac dec 100 1 10e6
;tran 0 10e-3 1e-3 1e-6
.noise V(vout1) V1 dec 100 10 20e3
```



References and Links

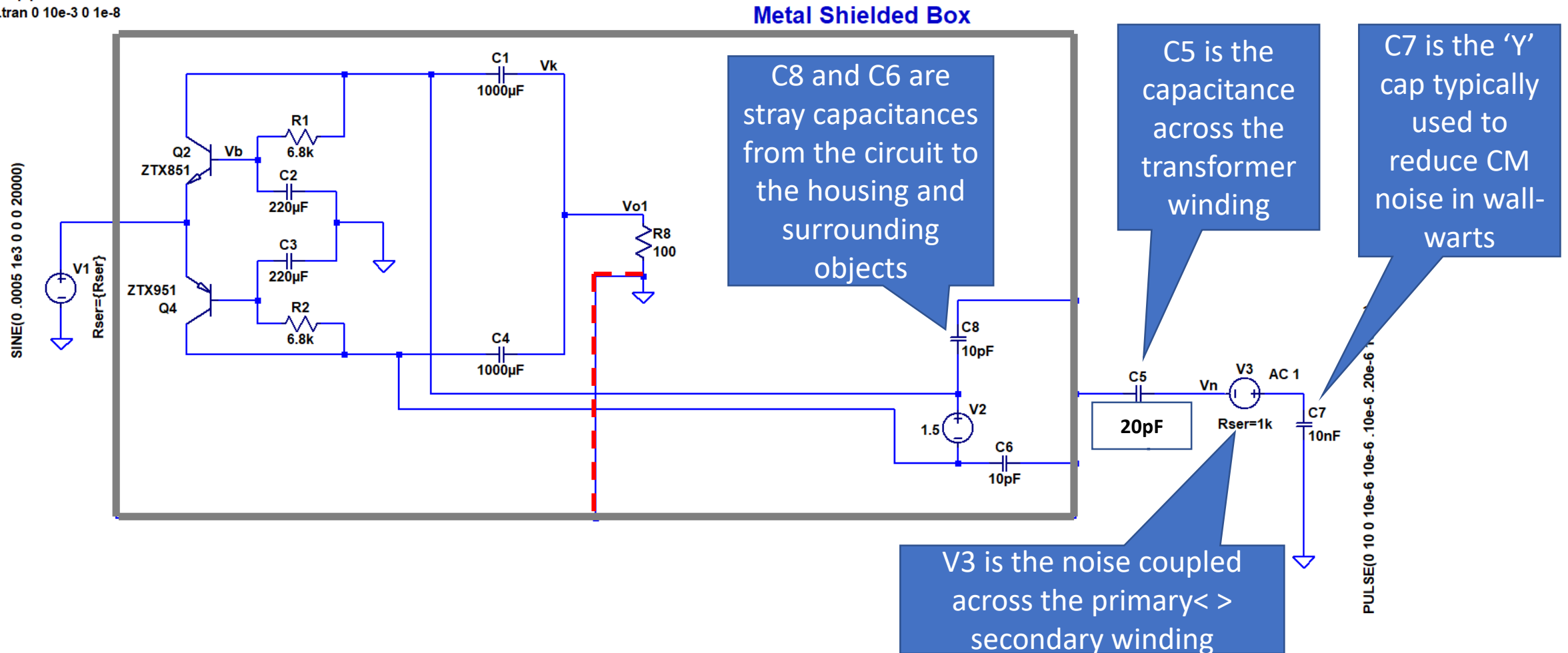
1. Noise in Transistor Circuits – Peter J Baxandall
2. Noise in Semiconductor Devices – Konczakowska and Wilamowski
3. The Art of Electronics 3rd Edition - Horowitz and Hill - Chapter 8 (pages 473 through 590)
4. Excellent MIT Physics Dept. Lecture Notes on Noise
5. Opamp noise opamp noise visualizer

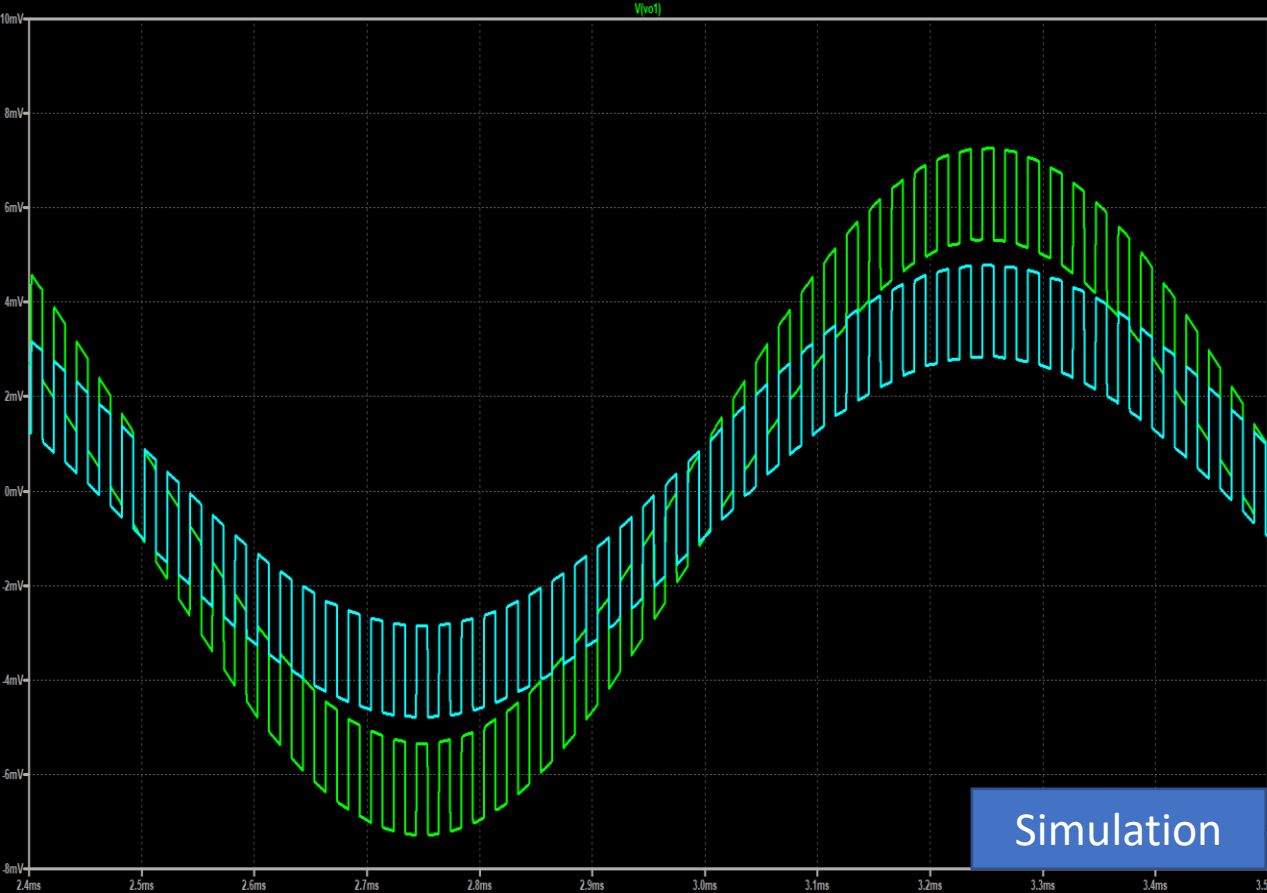
Miscellaneous Addenda

Noise in the Hawking and its Derivatives

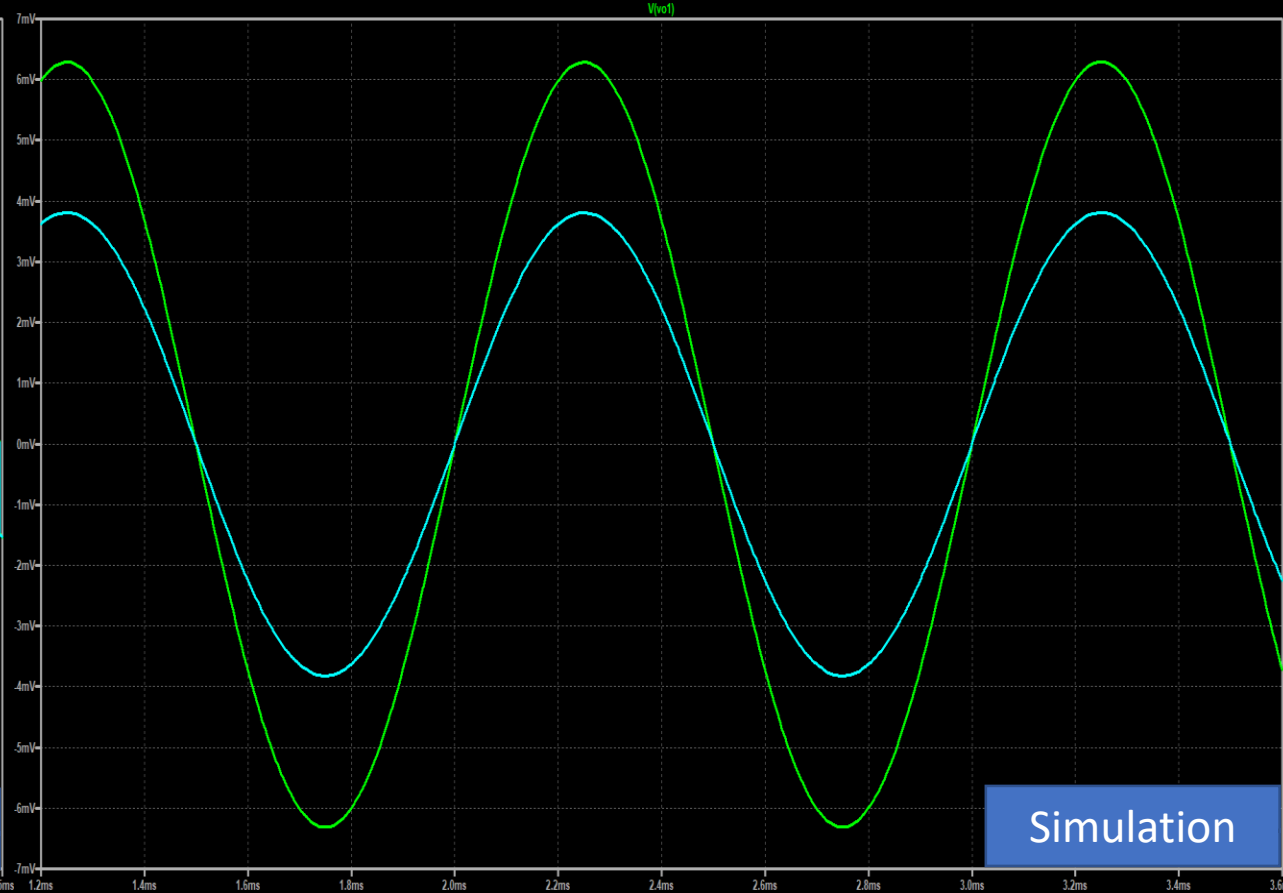
CM Noise Test

```
.four 20k V(vo1)
.param plotwinsize = 0
.param nummdgt = 15
;noise V(vo1) v1 dec 100 1 20E3
;ac dec 100 1 1000E6
.step param Rser 5 10 5
.tran 0 10e-3 0 1e-8
```





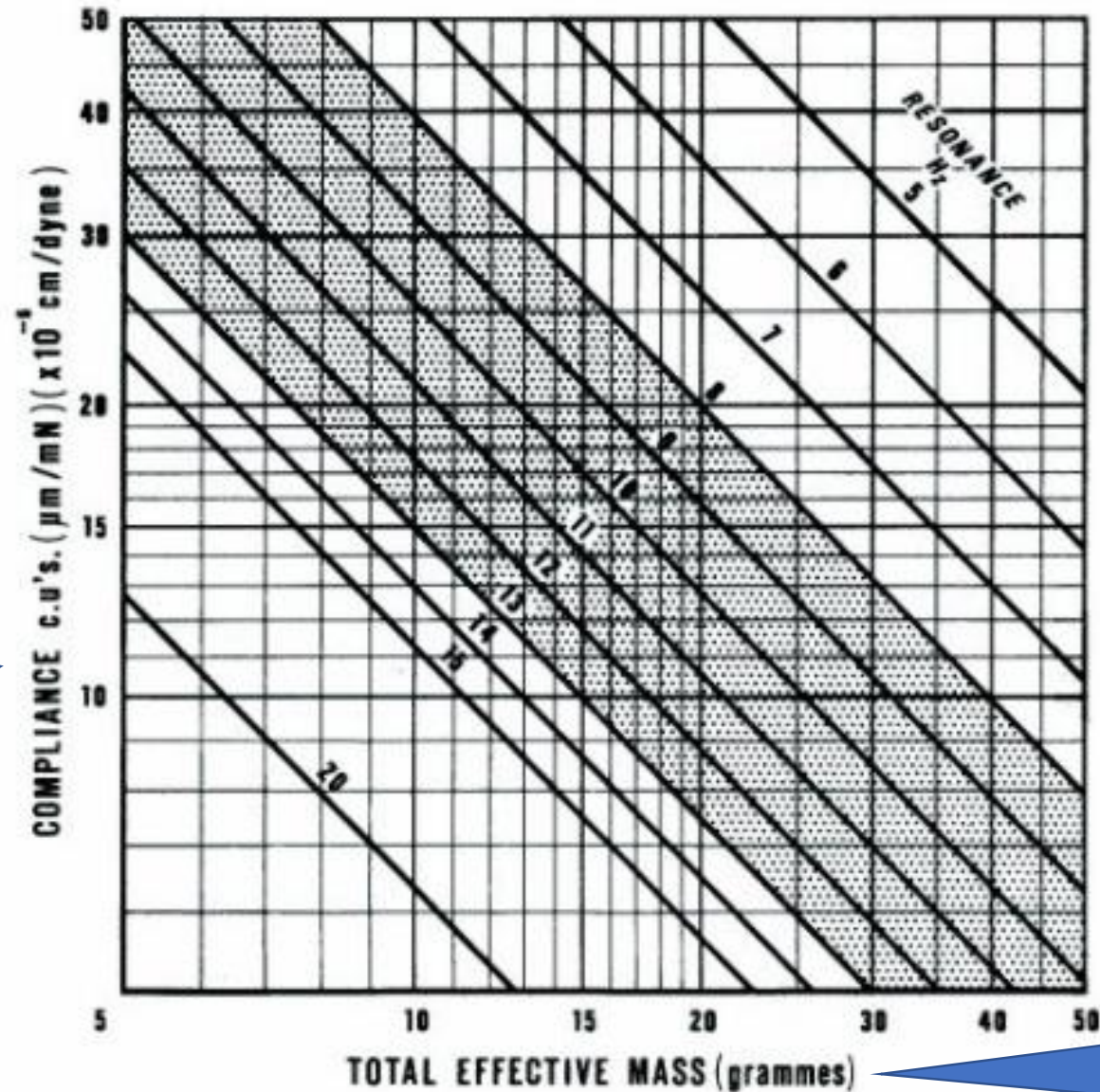
In the circuit on the previous page, the RED dashed connection from 0V to the metal housing is REMOVED to simulate non-shielded, non-grounded performance. With just 10pF stray coupling between the circuit and the housing and 20 pF between the primary and secondary of the power supply, HF noise (either switching from the use of an SMPSU or HF line conducted noise on the mains) makes the preamplifier unusable.



This simulation is exactly the same as the one on the left, but in this case, the metal box – i.e. shield – has been connected to the preamplifier 0V rail (dashed red connection on previous page circuit). This effectively shunts the stray capacitances directly to ground and away from the + and – supply rails, completely removing all noise on the output. A decent metal housing is an absolute necessity for these types of MC HA's as is connecting the metal housing to the circuit 0V (dashed RED line in the circuit). Very important note: DO NOT connect the metal housing to EARTH [Safety Ground] as this will create a severe earth loop.

How to
determine
arm<>cartridge
resonant
frequency

2. Cartridge
compliance from
manufactures
specifications



3. Diagonal line
intercept =
resultant
arm<>Cartridge
system
resonance

1. Effective arm mass
+ mass of the
cartridge

Graph courtesy SME

Fig. 1